



**THE DATASHEET OF  
MAX17113ETL+**



EVALUATION KIT  
AVAILABLE



## Low-Cost, Multiple-Output Power Supply for LCD TVs

MAX17113

### General Description

The MAX17113 multiple-output power-supply controller generates all the supply rails for thin-film transistor (TFT) liquid-crystal display (LCD) panels in TVs and monitors operating from a regulated 12V input. It includes a step-down and a step-up regulator, a positive and a negative charge pump, a Dual Mode™ logic-controlled high-voltage switch control block, and an adjustable-timing power-good output. The MAX17113 can operate from 8V to 16.5V input voltages and is optimized for LCD TV panel and LCD monitor applications running directly from 12V supplies.

The step-up and step-down regulators feature internal power MOSFETs and high-frequency operation allowing the use of small inductors and capacitors, resulting in a compact solution. Both switching regulators use fixed-frequency current-mode control architectures, providing fast load-transient response and easy compensation. A current-limit function for internal switches and output-fault shutdown protect the step-up and step-down power supplies against fault conditions. The MAX17113 provides soft-start functions to limit inrush current during startup. The MAX17113 provides adjustable power-up timing.

The positive and negative charge-pump regulators provide TFT gate-driver supply voltages. Both output voltages can be adjusted with external resistive voltage-dividers. The switch control block allows the manipulation of the positive TFT gate-driver voltage.

A series p-channel MOSFET is integrated to sequence power to AV<sub>DD</sub> after the MAX17113 has proceeded through normal startup, and provides True Shutdown™.

The MAX17113 is available in a small (5mm x 5mm), low-profile (0.8mm), 40-pin thin QFN package and operates over a -40°C to +85°C temperature range.

### Applications

LCD TV Panels  
LCD Monitor Panels

### Ordering Information

| PART         | TEMP RANGE     | PIN-PACKAGE     |
|--------------|----------------|-----------------|
| MAX17113ETL+ | -40°C to +85°C | 40 Thin QFN-EP* |

+Denotes a lead(Pb)-free/RoHS-compliant package.

\*EP = Exposed pad.

**Simplified Operating Circuit appears at end of data sheet.**

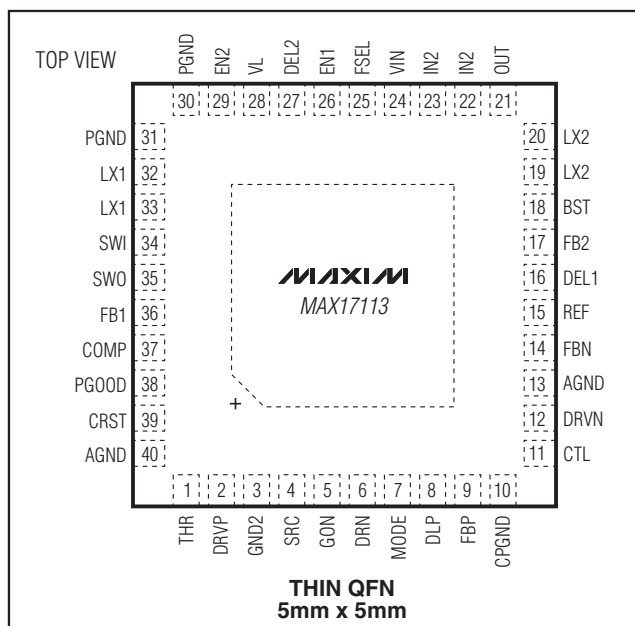
Dual Mode is a trademark of Maxim Integrated Products, Inc.

True Shutdown is a trademark of Maxim Integrated Products, Inc.

### Features

- ◆ Optimized for 10.8V to 13.2V Input Supply
- ◆ 8V to 16.5V Input Supply Range
- ◆ Selectable Frequency (450kHz/600kHz)
- ◆ Current-Mode Step-Up Regulator
  - Built-In 24V, 3.3A, 80mΩ n-Channel MOSFET
  - High-Accuracy Output Voltage (1%)
  - True Shutdown
  - Fast Load-Transient Response
  - High Efficiency
  - 10ms Internal Soft-Start
- ◆ Current-Mode Step-Down Regulator
  - Built-In 24V, 3A, 100mΩ n-Channel MOSFET
  - Fast Load-Transient Response
  - Adjustable Output Voltage Down to 1.5V
  - Skip Mode at Light Load (EN2 = AGND)
  - High Efficiency
  - 3ms Internal Soft-Start
- ◆ Adjustable Positive and Negative Charge-Pump Regulators
- ◆ Soft-Start and Timer-Delay Fault Latch for All Outputs
- ◆ Logic-Controlled High-Voltage Integrated Switches with Adjustable Delay
- ◆ 120mΩ p-Channel FET for AV<sub>DD</sub> Sequencing
- ◆ Input Undervoltage Lockout and Thermal-Overload Protection
- ◆ 40-Pin, 5mm x 5mm Thin QFN Package

### Pin Configuration



# Low-Cost, Multiple-Output Power Supply for LCD TVs

## ABSOLUTE MAXIMUM RATINGS

|  |                                    |
|--|------------------------------------|
| VIN, IN2, EN1, EN2, FSEL to AGND                   | -0.3V to +24V                      |
| CPGND, GND2, PGND to AGND                          | ±0.3V                              |
| MODE, DLP, CTL, THR, DEL1, DEL2, VL, PGOOD to AGND | -0.3V to +7.5V                     |
| REF, FBP, FBN, FB1, FB2, COMP, OUT, CRST to AGND   | -0.3V to (V <sub>VL</sub> + 0.3V)  |
| LX1, SWI, SWO to AGND                              | -0.3V to +24V                      |
| SWI to SWO   | -0.3V to +24V                      |
| DRVN to AGND                                       | -0.3V to (V <sub>IN2</sub> + 0.3V) |
| DRVN to AGND                                       | -0.3V to (V <sub>SWO</sub> + 0.3V) |
| LX2 to GND2  | -0.3V to (V <sub>IN2</sub> + 0.3V) |
| BST to VL  | -0.3V to +24V                      |
| SRC to AGND  | -0.3V to +48V                      |
| GON, DRN to AGND                                   | -0.3V to (V <sub>SRC</sub> + 0.3V) |
| SRC to DRN   | -0.3V to +40V                      |
| DRN to AGND  | -0.3V to +40V                      |
| GON to DRN   | -0.3V to +48V                      |
| REF Short Circuit to AGND                          | Continuous                         |

|   |                 |
|---|-----------------|
| RMS LX1 Current (total for both pins)                 | 3.2A            |
| RMS PGND Current (total for both pins)                | 3.2A            |
| RMS IN2 Current (total for both pins)                 | 3.2A            |
| RMS LX2 Current (total for both pins)                 | 3.2A            |
| RMS GND2, CPGND Current                               | 0.8A            |
| RMS SWI Current                                       | 2.4A            |
| RMS SWO Current                                       | 2.4A            |
| RMS DRVN, DRVP Current                                | 0.8A            |
| RMS VL Current  | 50mA            |
| Continuous Power Dissipation (T <sub>A</sub> = +70°C) |                 |
| 40-Pin Thin QFN (derate 35.7mW/°C above +70°C)        | 2857.1mW        |
| Operating Temperature Range                           | -40°C to +85°C  |
| Junction Temperature                                  | +160°C          |
| Storage Temperature Range                             | -65°C to +165°C |
| Lead Temperature (soldering, 10s)                     | +300°C          |

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

(Circuit of Figure 1, V<sub>VIN</sub> = V<sub>IN2</sub> = 12V, T<sub>A</sub> = 0°C to +85°C. Typical values are at T<sub>A</sub> = +25°C, unless otherwise noted.)

| PARAMETER   | CONDITIONS   | MIN | TYP  | MAX  | UNITS   |
|---|--|-----|------|------|---------|
| <b>GENERAL</b>  |  |     |      |      |         |
| VIN, IN2 Input Voltage Range  |  | 8.5 |      | 16.5 | V       |
| VIN + IN2 Quiescent Current   | Only LX2 switching (V <sub>FB1</sub> = V <sub>FBP</sub> = 1.5V, V <sub>FBN</sub> = 0V); EN1 = EN2 = VL, V <sub>FSEL</sub> = 0V                   |     | 10   |      | mA      |
| VIN + IN2 Standby Current   | LX2 not switching (V <sub>FB1</sub> = V <sub>FB2</sub> = V <sub>FBP</sub> = 1.5V, V <sub>FBN</sub> = 0V); EN1 = EN2 = VL, V <sub>FSEL</sub> = 0V |     | 3    |      | mA      |
| VIN + IN2 Shutdown Current  | EN1 = EN2 = AGND (shutdown)  |     | 300  | 600  | μA      |
| SWO Shutdown Current  | EN1 = EN2 = AGND (shutdown)  |     | 0.25 | 2    | μA      |
| SMPS Operating Frequency  | FSEL = VIN   | 510 | 600  | 690  | kHz     |
|   | FSEL = AGND  | 390 | 450  | 510  |         |
| Phase Difference Between Step-Down/Positive and Step-Up/Negative Regulators |  |     | 180  |      | Degrees |
| VIN Undervoltage Lockout Threshold  | VIN rising edge, 100mV typical hysteresis  | 6.0 | 7.0  | 8.3  | V       |
| <b>VL REGULATOR</b>   |  |     |      |      |         |
| VL Output Voltage   | I <sub>VL</sub> = 25mA, V <sub>FB1</sub> = V <sub>FB2</sub> = V <sub>FBP</sub> = 1.1V, V <sub>FBN</sub> = 0.4V (all regulators switching)        | 4.9 | 5.0  | 5.15 | V       |
| VL Undervoltage Lockout Threshold   | VL rising edge, 100mV typical hysteresis   | 3.6 | 4.0  | 4.5  | V       |

# Low-Cost, Multiple-Output Power Supply for LCD TVs

MAX17113

## ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 1,  $V_{VIN} = V_{IN2} = 12V$ ,  $T_A = 0^{\circ}C$  to  $+85^{\circ}C$ . Typical values are at  $T_A = +25^{\circ}C$ , unless otherwise noted.)

| PARAMETER                                   | CONDITIONS                              | MIN                               | TYP           | MAX   | UNITS      |   |
|---|---|-----------------------------------|---------------|-------|------------|---|
| <b>REFERENCE</b>                            |   |                                   |               |       |            |   |
| REF Output Voltage                          | No external load                        | 1.235                             | 1.250         | 1.265 | V          |   |
| REF Load Regulation                         | $0 < I_{LOAD} < 50\mu A$                |                                   |               | 10    | mV         |   |
| REF Sink Current                            | In regulation                           | 10                                |               |       | $\mu A$    |   |
| REF Undervoltage-Lockout Threshold          | Rising edge; 25mV typical hysteresis    |                                   | 1.0           | 1.2   | V          |   |
| <b>STEP-DOWN REGULATOR</b>                  |   |                                   |               |       |            |   |
| OUT Voltage in Fixed Mode                   | FB2 = AGND, no load<br>(Note 1)         | $0^{\circ}C < T_A < +85^{\circ}C$ | 3.25          | 3.30  | 3.35       | V |
|   |   | $T_A = +25^{\circ}C$              | 3.267         |       | 3.333      |   |
| FB2 Voltage in Adjustable Mode              | $V_{OUT} = 2.5V$ , no load<br>(Note 1)  | $0^{\circ}C < T_A < +85^{\circ}C$ | 1.23          | 1.25  | 1.27       | V |
|   |   | $T_A = +25^{\circ}C$              | 1.2375        |       | 1.2625     |   |
| FB2 Adjustable-Mode Threshold Voltage       | Dual-mode comparator                    | 0.10                              | 0.15          | 0.20  | V          |   |
| Output-Voltage Adjust Range                 | Step-down output                        | 1.5                               |               | 5.0   | V          |   |
| FB2 Fault Trip Level                        | Falling edge                            | 0.94                              | 1.00          | 1.06  | V          |   |
| FB2 Input Bias Current                      | $V_{FB2} = 1.5V$ , $T_A = +25^{\circ}C$ | 50                                | 125           | 200   | nA         |   |
| DC Load Regulation                          | $0.4A < I_{LOAD} < 2A$                  |                                   | 0.5           |       | %          |   |
| DC Line Regulation                          | No load, $10.8V < V_{IN2} < 13.2V$      |                                   | 0.05          |       | %/V        |   |
| LX2-to-IN2 nMOS Switch On-Resistance        |   |                                   | 100           | 200   | m $\Omega$ |   |
| LX2-to-CPGND nMOS Switch On-Resistance      |   | 7                                 | 12            | 25    | $\Omega$   |   |
| BST-to-VL pMOS Switch On-Resistance         |   | 7                                 | 12            | 25    | $\Omega$   |   |
| Low-Frequency Operation OUT Threshold       | Step-down only                          |                                   | 0.8           |       | V          |   |
| Low-Frequency Operation Switching Frequency | FSEL = VIN                              |                                   | 100           |       | kHz        |   |
|   | FSEL = AGND                             |                                   | 75            |       |            |   |
| LX2 Positive Current Limit                  |   | 2.50                              | 3             | 3.50  | A          |   |
| Soft-Start Period                           |   |                                   | 3.3           |       | ms         |   |
| Soft-Start Step Size                        |   |                                   | $V_{REF}/128$ |       | V          |   |
| Maximum Duty Factor                         |   | 65                                | 75            | 90    | %          |   |
| <b>POWER-GOOD</b>                           |   |                                   |               |       |            |   |
| FB2 Power-Good Threshold                    | FB2 rising                              | 0.94                              | 1.00          | 1.06  | V          |   |
| FB2 Threshold Hysteresis                    |   |                                   | 12            |       | mV         |   |
| PGOOD Output Low Voltage                    | $I_{PGOOD} = 1mA$                       |                                   | 0.1           | 0.3   | V          |   |
| PGOOD Leakage Current                       | $V_{PGOOD} = 3V$ , $T_A = +25^{\circ}C$ |                                   |               | 1     | $\mu A$    |   |
| CRST Charge Current                         | $V_{CRST} = 1V$                         | 0.8                               | 1.0           | 1.2   | $\mu A$    |   |
| CRST Voltage Threshold                      |   | 1.2                               | 1.25          | 1.3   | V          |   |
| CRST Pulldown Resistance                    | $V_{CRST} = 1V$                         |                                   | 150           | 300   | $\Omega$   |   |

# Low-Cost, Multiple-Output Power Supply for LCD TVs

## ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 1,  $V_{VIN} = V_{IN2} = 12V$ ,  $T_A = 0^\circ C$  to  $+85^\circ C$ . Typical values are at  $T_A = +25^\circ C$ , unless otherwise noted.)

| PARAMETER   | CONDITIONS                                    |                                 | MIN       | TYP           | MAX    | UNITS      |
|---|---|---------------------------------|-----------|---------------|--------|------------|
| <b>STEP-UP REGULATOR</b>                            |   |                                 |           |               |        |            |
| Output-Voltage Range                                |   |                                 | $V_{VIN}$ |               | 18     | V          |
| Minimum $t_{ON}$                                    |   |                                 |           | 70            | 100    | ns         |
| FB1 Regulation Voltage                              | FB1 = COMP,<br>$C_{COMP} = 1mF$               | $T_A = +25^\circ C$             | 1.2375    | 1.250         | 1.2625 | V          |
|   |   | $0^\circ C < T_A < +85^\circ C$ | 1.225     |               | 1.275  |            |
| FB1 Fault Threshold                                 | FB rising, hysteresis = 12mV                  |                                 | 0.96      | 1.0           | 1.06   | V          |
| FB1 UVLO Threshold                                  |   |                                 | 0.05      | 0.125         | 0.2    | V          |
| FB1 Load Regulation                                 | $0A < I_{LOAD} < \text{full}$                 |                                 |           | 0.5           |        | %          |
| FB1 Line Regulation                                 | $10.8V < V_{IN} < 13.2V$                      |                                 |           | 0.08          | 0.15   | %/V        |
| FB1 Input Bias Current                              | $V_{FB1} = 1.25V$                             |                                 | 20        | 125           | 300    | nA         |
| FB1 Transconductance                                | $\Delta I = \pm 2.5\mu A$ at COMP, FB1 = COMP |                                 | 125       | 320           | 600    | $\mu S$    |
| FB1 Voltage Gain                                    | FB1 to COMP                                   |                                 |           | 1400          |        | V/V        |
| LX1 Leakage Current                                 | $V_{FB1} = 1.5V$ , $V_{LX1} = 20V$            |                                 |           | 10            | 25     | $\mu A$    |
| LX1 Current Limit                                   | $V_{FB1} = 1.1V$ , duty cycle = 25%           |                                 | 2.8       | 3.3           | 3.8    | A          |
| Current-Sense Transresistance                       |   |                                 | 0.1       | 0.2           | 0.30   | V/A        |
| LX1 On-Resistance                                   |   |                                 |           | 80            | 200    | m $\Omega$ |
| Soft-Start Period                                   |   |                                 |           | 10            |        | ms         |
| Soft-Start Step Size                                |   |                                 |           | $I_{LIM}/128$ |        | A          |
| <b>POSITIVE AND NEGATIVE CHARGE-PUMP REGULATORS</b> |   |                                 |           |               |        |            |
| FBP Regulation Voltage                              | $0^\circ C < T_A < +85^\circ C$               |                                 | 1.23      | 1.25          | 1.27   | V          |
|   | $T_A = +25^\circ C$                           |                                 | 1.2375    |               | 1.2625 |            |
| FBP Line-Regulation Error                           | $11V < V_{SUP} < 16V$ , not in dropout        |                                 |           | 0.01          | 0.2    | %/V        |
| FBP Input Bias Current                              | $V_{FBP} = 1.5V$ , $T_A = +25^\circ C$        |                                 | -50       |               | +50    | nA         |
| DRVP p-Channel MOSFET On-Resistance                 |   |                                 |           | 2.0           | 4.0    | $\Omega$   |
| DRVP n-Channel MOSFET On-Resistance                 |   |                                 |           | 0.8           | 1.5    | $\Omega$   |
| FBP Fault Trip Level                                | Falling edge                                  |                                 | 0.96      | 1.02          | 1.08   | V          |
| Positive Charge-Pump Soft-Start Period              |   |                                 |           | 3.3           |        | ms         |
| Positive Charge-Pump Soft-Start Step Size           |   |                                 |           | $V_{REF}/128$ |        | V          |
| FBN Regulation Voltage                              | $V_{REF} - V_{FBN}$                           | $0^\circ C < T_A < +85^\circ C$ | 0.985     | 1.000         | 1.015  | V          |
|   |   | $T_A = +25^\circ C$             | 0.99      | 1.00          | 1.01   |            |
| FBN Input Bias Current                              | $V_{FBN} = 250mV$ , $T_A = +25^\circ C$       |                                 | -50       |               | +50    | nA         |
| FBN Line Regulation Error                           | $11V < V_{SUP} < 16V$ , not in dropout        |                                 |           | 0.01          | 0.2    | %/V        |
| DRVN p-Channel On-Resistance                        |   |                                 |           | 2.0           | 4.0    | $\Omega$   |
| DRVN n-Channel On-Resistance                        |   |                                 |           | 0.8           | 1.5    | $\Omega$   |
| FBN Fault Trip Level                                | Rising edge                                   |                                 | 450       | 500           | 550    | mV         |

# Low-Cost, Multiple-Output Power Supply for LCD TVs

MAX1713

## ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 1,  $V_{VIN} = V_{IN2} = 12V$ ,  $T_A = 0^{\circ}C$  to  $+85^{\circ}C$ . Typical values are at  $T_A = +25^{\circ}C$ , unless otherwise noted.)

| PARAMETER  | CONDITIONS  | MIN   | TYP                       | MAX   | UNITS      |
|--|---|-------|---------------------------|-------|------------|
| Negative Charge-Pump Soft-Start Period                           |   |       | 2                         |       | ms         |
| Negative Charge-Pump Soft-Start Step Size                        |   |       | $(V_{REF} - V_{FBN})/128$ |       | V          |
| <b>AVDD SWITCH</b>   |   |       |                           |       |            |
| SWI Supply Range   |   | 8.0   |                           | 18.5  | V          |
| SWI Overvoltage Fault Threshold                                  | SWI rising edge, 300mV typical hysteresis (Note 2)  | 18.50 | 19.2                      | 19.90 | V          |
| SWI-SWO Switch Resistance  |   |       | 120                       | 250   | m $\Omega$ |
| <b>HIGH-VOLTAGE SWITCH ARRAY</b>                                 |   |       |                           |       |            |
| SRC Supply Range   |   |       |                           | 44    | V          |
| SRC Supply Current   |   |       | 250                       | 500   | $\mu$ A    |
| GON-to-SRC Switch On-Resistance                                  | $V_{DLP} = 2V$ , CTL = VL   |       | 10                        | 20    | $\Omega$   |
| GON-to-SRC Switch Saturation Current                             | $(V_{SRC} - V_{GON}) > 5V$  | 180   | 390                       |       | mA         |
| GON-to-DRN Switch On-Resistance                                  | $V_{DLP} = 2V$ , CTL = AGND   |       | 25                        | 50    | $\Omega$   |
| GON-to-DRN Switch Saturation Current                             | $(V_{GON} - V_{DRN}) > 5V$  | 40    | 180                       |       | mA         |
| GON-to-GND Switch On-Resistance                                  | DLP = AGND, $V_{GON} = 5V$  |       | 5                         | 10    | k $\Omega$ |
| CTL Input Low Voltage  |   |       |                           | 0.6   | V          |
| CTL Input High Voltage   |   | 1.6   |                           |       | V          |
| CTL Input Current  | CTL = AGND or VL, $T_A = +25^{\circ}C$  | -1    |                           | +1    | $\mu$ A    |
| CTL-to-GON Rising Propagation Delay                              | 1k $\Omega$ from DRN to GND, CTL = AGND to VL step, no load on GON, measured from $V_{CTL} = 2V$ to GON = 20%   |       | 100                       |       | ns         |
| CTL-to-GON Falling Propagation Delay                             | 1k $\Omega$ from DRN to GND, CTL = VL to AGND step, no load on GON, measured from $V_{CTL} = 0.6V$ to GON = 80% |       | 200                       |       | ns         |
| MODE Switch On-Resistance  |   |       | 1200                      |       | $\Omega$   |
| Mode 1 Voltage Threshold   | $V_{MODE}$ rising   |       | 3.8                       | 4.1   | V          |
| MODE Capacitor Charge Current (Mode 2)                           | $V_{MODE} = 1V$   | 40    | 50                        | 65    | $\mu$ A    |
| MODE Voltage Threshold for Enabling DRN Switch Control in Mode 2 | GON connects to DRN   | 1.15  | 1.25                      | 1.35  | V          |
| MODE Current-Source Stop Voltage Threshold                       | MODE rising   | 2     |                           | 3     | V          |
| THR-to-GON Voltage Gain  |   | 9.4   | 10.0                      | 10.6  | V/V        |
| <b>SEQUENCE CONTROL</b>  |   |       |                           |       |            |
| EN1, EN2 Input Low Voltage                                       |   |       |                           | 0.6   | V          |
| EN1, EN2 Input High Voltage                                      |   | 1.6   |                           |       | V          |
| EN1, EN2 Pulldown Resistance                                     |   |       | 1                         |       | M $\Omega$ |
| DEL1, DEL2, DLP Charge Current                                   | $V_{DEL1} = V_{DEL2} = V_{DLP} = 1V$  | 7     | 8                         | 9     | $\mu$ A    |
| DEL1, DEL2, DLP Turn-On Threshold                                |   | 1.2   | 1.25                      | 1.32  | kV         |
| DEL1, DEL2, DLP Discharge Switch On-Resistance                   | EN1 = AGND or fault tripped   |       | 10                        |       | $\Omega$   |
| FBN Discharge Switch On-Resistance                               | EN2 = AGND or fault tripped   |       | 3                         |       | k $\Omega$ |

# Low-Cost, Multiple-Output Power Supply for LCD TVs

## ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 1,  $V_{VIN} = V_{IN2} = 12V$ ,  $T_A = 0^{\circ}C$  to  $+85^{\circ}C$ . Typical values are at  $T_A = +25^{\circ}C$ , unless otherwise noted.)

| PARAMETER                                  | CONDITIONS              | MIN | TYP  | MAX | UNITS |
|--|-------------------------|-----|------|-----|-------|
| <b>FAULT DETECTION</b>                     |                         |     |      |     |       |
| Duration to Trigger Fault                  |                         | 45  | 55   | 65  | ms    |
| Duration to Restart After Fault            |                         |     | 240  |     | ms    |
| Number of Restart Attempts Before Shutdown |                         |     | 3    |     | Times |
| Thermal-Shutdown Threshold                 | 15°C typical hysteresis |     | +160 |     | °C    |
| <b>SWITCHING FREQUENCY SELECTION</b>       |                         |     |      |     |       |
| FSEL Input Low Voltage                     | 450kHz                  |     |      | 0.6 | V     |
| FSEL Input High Voltage                    | 600kHz                  | 1.6 |      |     | V     |
| FSEL Pulldown Resistance                   |                         |     | 1    |     | MΩ    |

## ELECTRICAL CHARACTERISTICS

(Circuit of Figure 1,  $V_{VIN} = V_{IN2} = 12V$ ,  $T_A = -40^{\circ}C$  to  $+85^{\circ}C$ . Typical values are at  $T_A = +25^{\circ}C$ , unless otherwise noted.) (Note 3)

| PARAMETER                             | CONDITIONS   | MIN   | TYP | MAX   | UNITS |
|---------------------------------------|--|-------|-----|-------|-------|
| <b>GENERAL</b>                        |  |       |     |       |       |
| VIN + IN2 Input-Voltage Range         |  | 8.5   |     | 16.5  | V     |
| VIN + IN2 Shutdown Current            | EN1 = EN2 = AGND (shutdown)  |       |     | 600   | μA    |
| SWO Shutdown Current                  | EN1 = EN2 = AGND (shutdown)  |       |     | 2     | μA    |
| SMPS Operating Frequency              | FSEL = VIN   | 510   |     | 690   | kHz   |
|                                       | FSEL = AGND  | 390   |     | 510   |       |
| VIN Undervoltage-Lockout Threshold    | VIN rising edge, 100mV typical hysteresis  | 5.75  |     | 7.25  | V     |
| <b>VL REGULATOR</b>                   |  |       |     |       |       |
| VL Output Voltage                     | $I_{VL} = 25mA$ , $V_{FB1} = V_{FB2} = V_{FBP} = 1.1V$ , $V_{FBN} = 0.4V$ (all regulators switching) | 4.9   |     | 5.15  | V     |
| VL Undervoltage-Lockout Threshold     | VL rising edge, 100mV typical hysteresis   | 3.6   |     | 4.5   | V     |
| <b>REFERENCE</b>                      |  |       |     |       |       |
| REF Output Voltage                    | No external load   | 1.235 |     | 1.265 | V     |
| REF Load Regulation                   | $0 < I_{LOAD} < 50\mu A$   |       |     | 10    | mV    |
| REF Undervoltage-Lockout Threshold    | Rising edge; 25mV typical hysteresis   |       |     | 1.2   | V     |
| <b>STEP-DOWN REGULATOR</b>            |  |       |     |       |       |
| OUT Voltage in Fixed Mode             | FB2 = GND, no load (Note 1)  | 3.25  |     | 3.35  | V     |
| FB2 Voltage in Adjustable Mode        | $V_{OUT} = 2.5V$ , no load (Note 1)  | 1.23  |     | 1.27  | V     |
| FB2 Adjustable-Mode Threshold Voltage | Dual-mode comparator   | 0.10  |     | 0.20  | V     |
| Output-Voltage Adjust Range           | Step-down output   | 1.5   |     | 5.0   | V     |

# Low-Cost, Multiple-Output Power Supply for LCD TVs

MAX1713

## ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 1,  $V_{VIN} = V_{IN2} = 12V$ ,  $T_A = -40^{\circ}C$  to  $+85^{\circ}C$ . Typical values are at  $T_A = +25^{\circ}C$ , unless otherwise noted.) (Note 3)

| PARAMETER   | CONDITIONS  | MIN       | TYP | MAX   | UNITS      |
|---|---|-----------|-----|-------|------------|
| LX2-to-IN2 nMOS Switch On-Resistance                |   |           |     | 200   | m $\Omega$ |
| LX2-to-CPGND nMOS Switch On-Resistance              |   | 7         |     | 25    | $\Omega$   |
| BST-to-VL pMOS Switch On-Resistance                 |   | 7         |     | 25    | $\Omega$   |
| LX2 Positive Current Limit                          |   | 2.50      |     | 3.50  | A          |
| Maximum Duty Factor                                 |   | 65        |     | 90    | %          |
| FB2 Power-Good Threshold                            | FB2 rising  | 0.94      |     | 1.06  | V          |
| PGOOD Output Low Voltage                            | $I_{PGOOD} = 1mA$                                     |           |     | 0.3   | V          |
| CRST Charge Current                                 | $V_{CRST} = 1V$                                       | 0.8       |     | 1.2   | $\mu A$    |
| CRST Voltage Threshold                              |   | 1.2       |     | 1.3   | V          |
| CRST Pulldown Resistance                            | $V_{CRST} = 1V$                                       |           |     | 300   | $\Omega$   |
| <b>STEP-UP REGULATOR</b>                            |   |           |     |       |            |
| Output-Voltage Range                                |   | $V_{VIN}$ |     | 18    | V          |
| Oscillator Maximum Duty Cycle                       |   | 65        |     | 90    | %          |
| FB1 Regulation Voltage                              | FB1 = COMP, $C_{COMP} = 1nF$                          | 1.225     |     | 1.275 | V          |
| LX1 Current Limit                                   | $V_{FB1} = 1.1V$ , duty cycle = 25%                   | 3.2       |     | 4.2   | A          |
| Current-Sense Transresistance                       |   | 0.10      |     | 0.30  | V/A        |
| LX1 On-Resistance                                   |   |           |     | 200   | m $\Omega$ |
| <b>POSITIVE AND NEGATIVE CHARGE-PUMP REGULATORS</b> |   |           |     |       |            |
| FBP Regulation Voltage                              |   | 1.23      |     | 1.27  | V          |
| DRVP p-Channel MOSFET On-Resistance                 |   |           |     | 4     | $\Omega$   |
| DRVP n-Channel MOSFET On-Resistance                 |   |           |     | 1.5   | $\Omega$   |
| FBN Regulation Voltage                              | $V_{REF} - V_{FBN}$                                   | 0.985     |     | 1.015 | V          |
| DRVN p-Channel On-Resistance                        |   |           |     | 3     | $\Omega$   |
| DRVN n-Channel On-Resistance                        |   |           |     | 1.5   | $\Omega$   |
| <b>AVDD SWITCH</b>                                  |   |           |     |       |            |
| SWI Supply Range                                    |   | 8.0       |     | 18.5  | V          |
| SWI Overvoltage Fault Threshold                     | $V_{SWI} =$ rising, 300mV typical hysteresis (Note 3) | 18.5      |     | 19.9  | V          |
| SWI-SWO Switch Resistance                           |   |           |     | 360   | m $\Omega$ |
| <b>HIGH-VOLTAGE SWITCH ARRAY</b>                    |   |           |     |       |            |
| SRC Supply Range                                    |   |           |     | 44    | V          |
| GON-to-SRC Switch On-Resistance                     | $V_{DLP} = 2V$ , CTL = VL                             |           |     | 20    | $\Omega$   |
| GON-to-DRN Switch On-Resistance                     | $V_{DLP} = 2V$ , CTL = AGND                           |           |     | 50    | $\Omega$   |
| GON-to-GND Switch On-Resistance                     | DLP = AGND, $V_{GON} = 5V$                            | 2.5       |     | 10    | k $\Omega$ |
| CTL Input Low Voltage                               |   |           |     | 0.6   | V          |
| CTL Input High Voltage                              |   | 1.6       |     |       | V          |
| Mode 1 Voltage Threshold                            | $V_{MODE}$ rising edge                                |           |     | 4.1   | V          |

# Low-Cost, Multiple-Output Power Supply for LCD TVs

## ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 1,  $V_{IN} = V_{IN2} = 12V$ ,  $T_A = -40^{\circ}C$  to  $+85^{\circ}C$ . Typical values are at  $T_A = +25^{\circ}C$ , unless otherwise noted.) (Note 3)

| PARAMETER  | CONDITIONS          | MIN  | TYP | MAX  | UNITS |
|--|---------------------|------|-----|------|-------|
| MODE Voltage Threshold for Enabling DRN Switch Control in Mode 2 | GON connects to DRN | 1.15 |     | 1.35 | V     |
| MODE Current-Source Stop Voltage Threshold                       | MODE rising         | 2    |     | 3    | V     |
| THR-to-GON Voltage Gain  |                     | 9.4  |     | 10.6 | V/V   |
| <b>SEQUENCE CONTROL</b>  |                     |      |     |      |       |
| EN1, EN2 Input Low Voltage                                       |                     |      |     | 0.6  | V     |
| EN1, EN2 Input High Voltage                                      |                     | 1.6  |     |      | V     |
| <b>SWITCHING FREQUENCY SELECTION</b>                             |                     |      |     |      |       |
| FSEL Input Low Voltage   | 600kHz              |      |     | 0.6  | V     |
| FSEL Input High Voltage  | 1.2MHz              | 1.6  |     |      | V     |

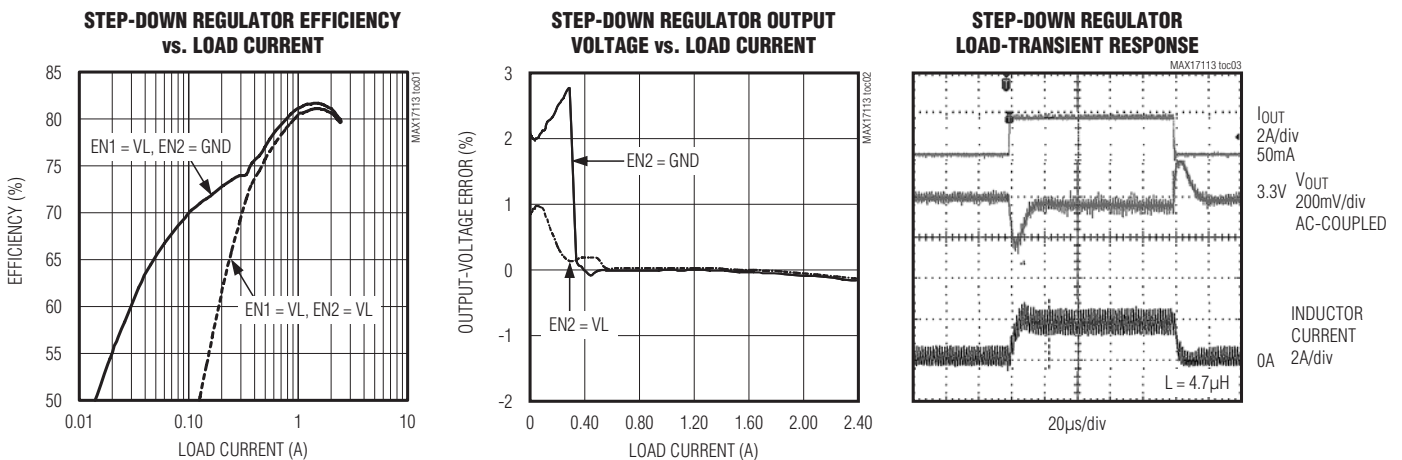
**Note 1:** When the inductor is in continuous conduction ( $EN2 = VL$  or heavy load), the output voltage has a DC regulation level lower than the error comparator threshold by 50% of the output-voltage ripple. In discontinuous conduction ( $EN2 = GND$  with light load), the output voltage has a DC regulation level higher than the error comparator threshold by 50% of the output-voltage ripple.

**Note 2:** Disables boost switching if either SUP, SW1, or OVIN exceeds the threshold. Switching resumes when no threshold is exceeded.

**Note 3:** Specifications to  $T_A = -40^{\circ}C$  are guaranteed by design, not production tested.

## Typical Operating Characteristics

(Circuit of Figure 1.  $V_{IN} = V_{INL} = V_{SUPP} = 12V$ ,  $AV_{DD} = 16V$ ,  $V_{GON} = 34.5V$ ,  $V_{GOFF} = -6V$ ,  $V_{OUT1} = 3.3V$ ,  $T_A = +25^{\circ}C$ , unless otherwise noted.)



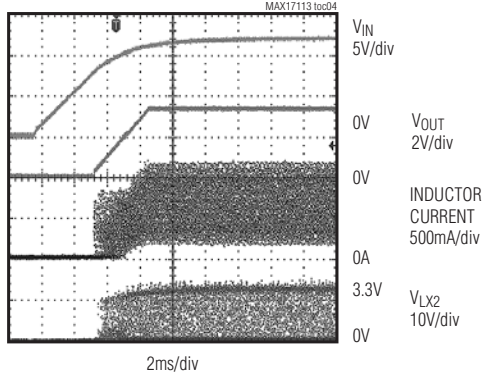
# Low-Cost, Multiple-Output Power Supply for LCD TVs

MAX17113

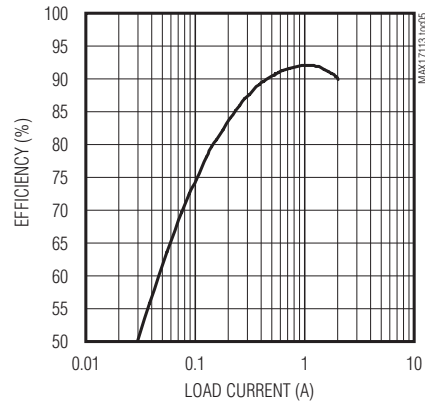
## Typical Operating Characteristics (continued)

(Circuit of Figure 1.  $V_{IN} = V_{INL} = V_{SUPP} = 12V$ ,  $V_{DD} = 16V$ ,  $V_{GON} = 34.5V$ ,  $V_{GOFF} = -6V$ ,  $V_{OUT1} = 3.3V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

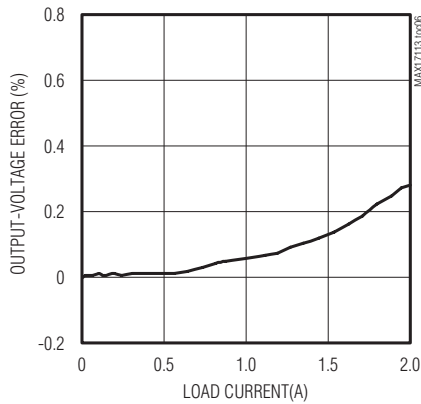
**STEP-DOWN REGULATOR  
SOFT-START (HEAVY LOAD)**



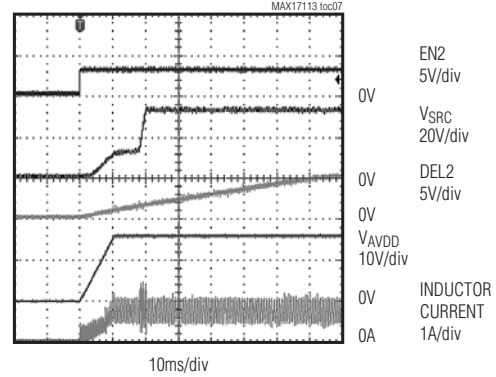
**STEP-UP REGULATOR EFFICIENCY  
vs. LOAD CURRENT**



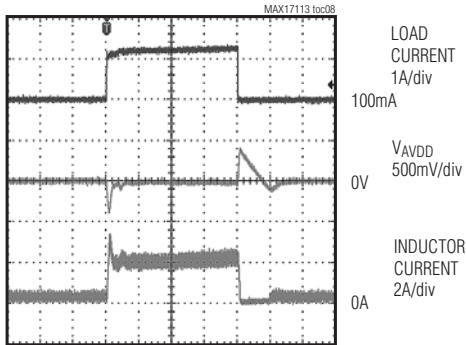
**STEP-UP REGULATOR  
OUTPUT VOLTAGE vs. LOAD CURRENT**



**STEP-DOWN REGULATOR  
SOFT-START (HEAVY LOAD)**

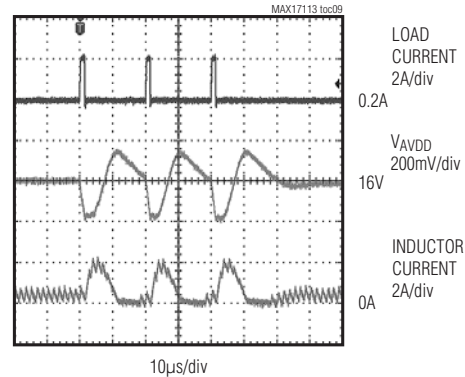


**STEP-UP REGULATOR  
LOAD-TRANSIENT RESPONSE**



$R_{COMP} = 50.5k\Omega$   
 $C_{COMP} = 330pF$

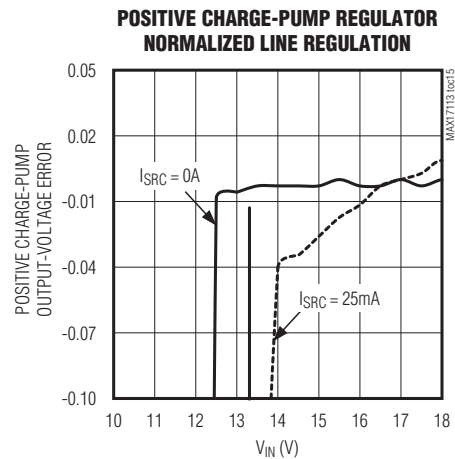
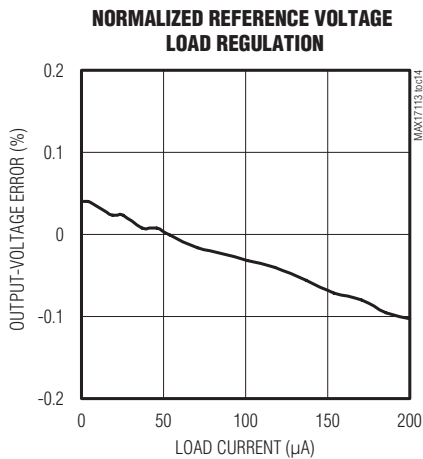
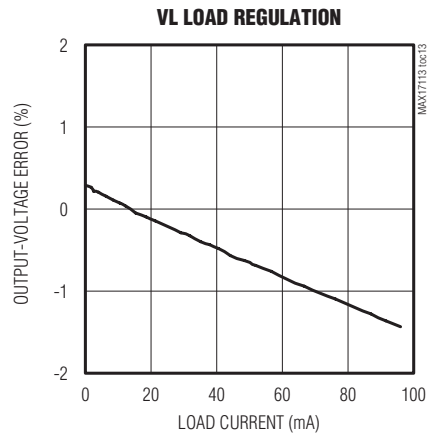
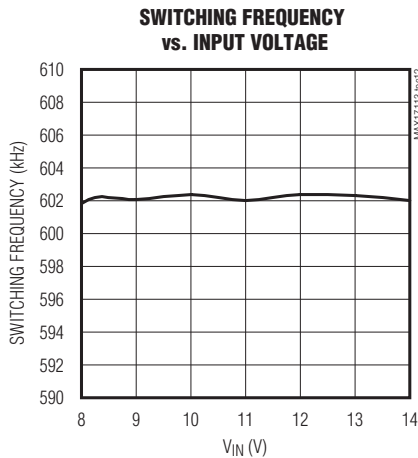
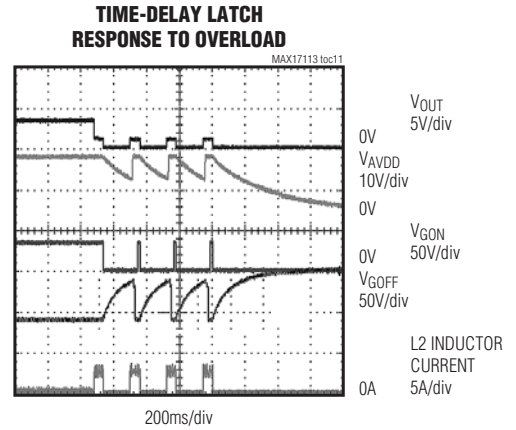
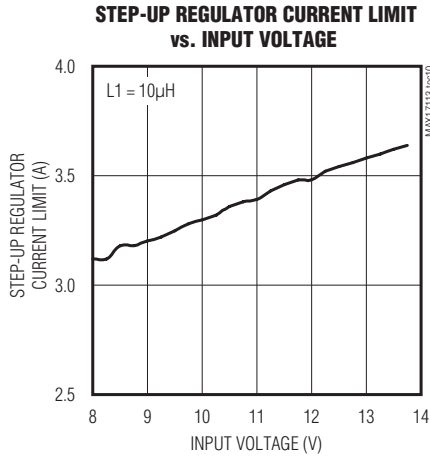
**STEP-UP REGULATOR PULSED  
LOAD-TRANSIENT RESPONSE**



# Low-Cost, Multiple-Output Power Supply for LCD TVs

## Typical Operating Characteristics (continued)

(Circuit of Figure 1.  $V_{IN} = V_{INL} = V_{SUPP} = 12V$ ,  $V_{DD} = 16V$ ,  $V_{GON} = 34.5V$ ,  $V_{GOFF} = -6V$ ,  $V_{OUT1} = 3.3V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

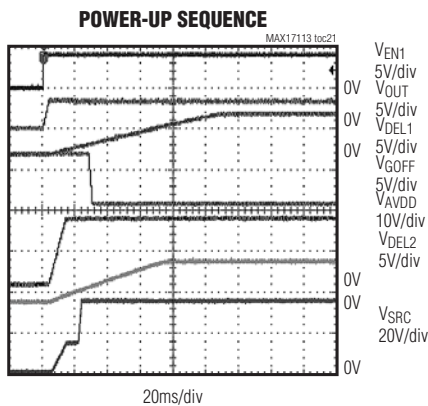
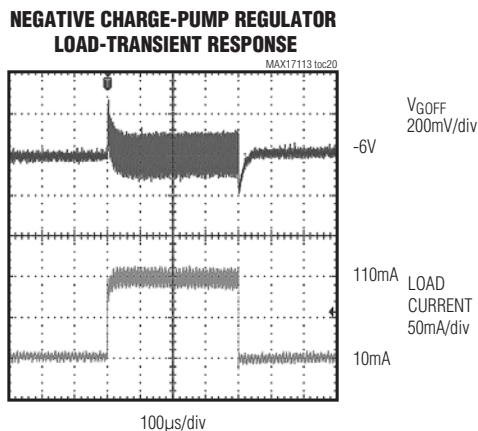
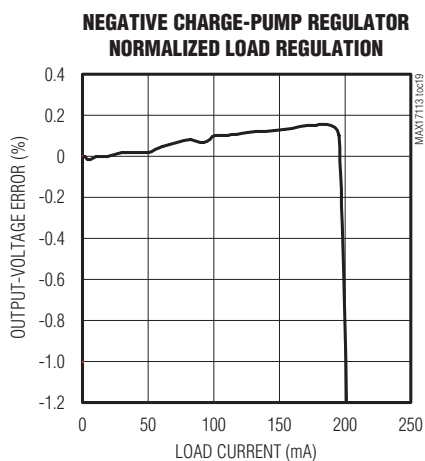
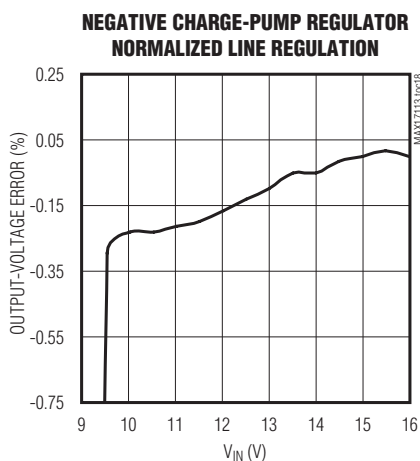
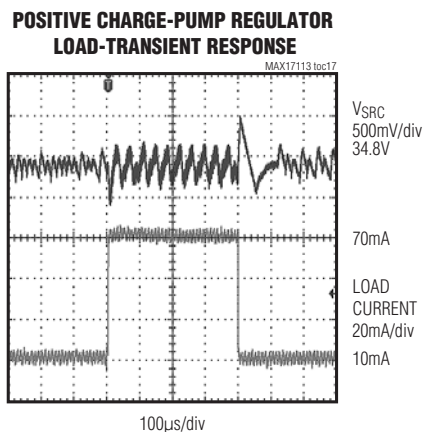
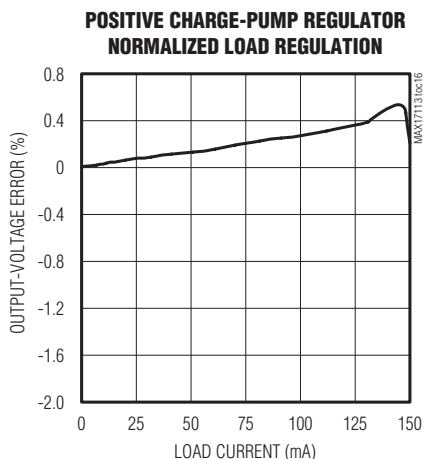


# Low-Cost, Multiple-Output Power Supply for LCD TVs

MAX17113

## Typical Operating Characteristics (continued)

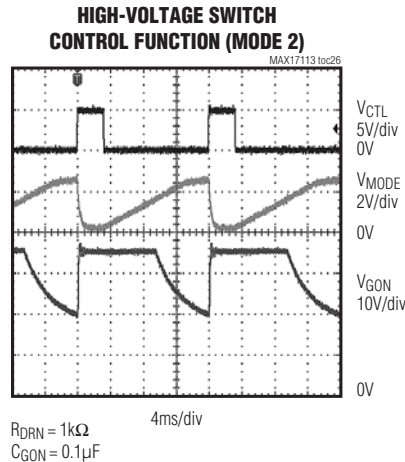
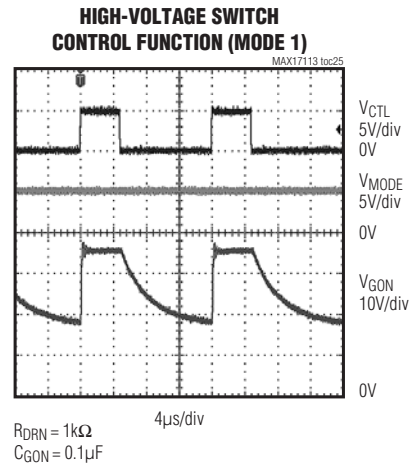
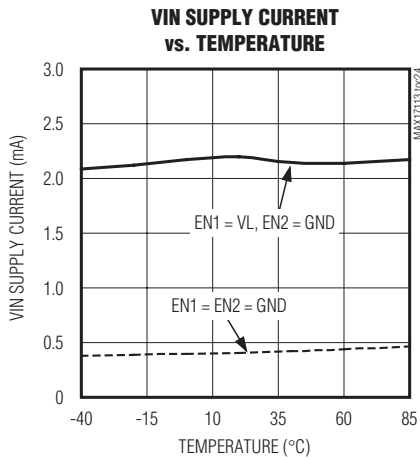
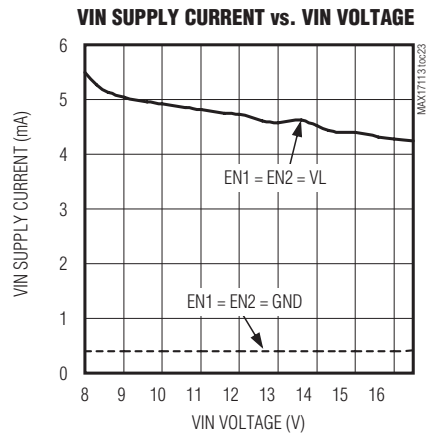
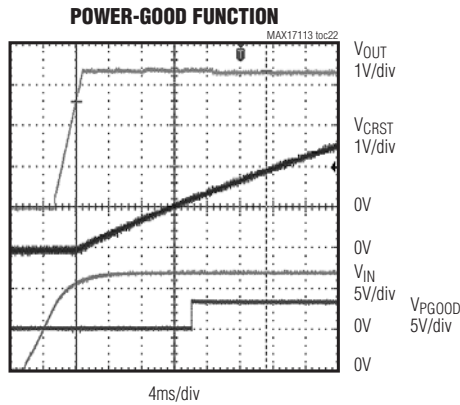
(Circuit of Figure 1.  $V_{IN} = V_{INL} = V_{SUPP} = 12V$ ,  $V_{DD} = 16V$ ,  $V_{GON} = 34.5V$ ,  $V_{GOFF} = -6V$ ,  $V_{OUT1} = 3.3V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)



# Low-Cost, Multiple-Output Power Supply for LCD TVs

## Typical Operating Characteristics (continued)

(Circuit of Figure 1.  $V_{IN} = V_{INL} = V_{SUPP} = 12V$ ,  $A_{VDD} = 16V$ ,  $V_{GON} = 34.5V$ ,  $V_{GOFF} = -6V$ ,  $V_{OUT1} = 3.3V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)



# Low-Cost, Multiple-Output Power Supply for LCD TVs

## Pin Description

MAX17113

| PIN    | NAME  | FUNCTION  |
|--------|-------|---|
| 1      | THR   | GON Low-Level Regulation Set-Point Input. Connects THR to the center of a resistive voltage-divider between AVDD and GND to set the $V_{GON}$ falling regulation level. The actual level is $10 \times V_{THR}$ . See the <i>High-Voltage Switch Control</i> section for details.   |
| 2      | DRVVP | Positive Charge-Pump Driver Output. Connects DRVVP to the positive charge-pump flying capacitor(s).   |
| 3      | GND2  | Internal Buck LSS Power Ground  |
| 4      | SRC   | Switch Input. Source of the internal high-voltage p-channel MOSFET between SRC and GON.   |
| 5      | GON   | Internal High-Voltage MOSFET Switch Common Terminal. GON is the output of the high-voltage switch-control block.  |
| 6      | DRN   | Switch Input. Drain of the internal high-voltage p-channel MOSFET connected to GON.   |
| 7      | MODE  | High-Voltage Switch-Control Block Mode Selection Input and Timing-Adjustment Input. See the <i>High-Voltage Switch Control</i> section for details. MODE is high impedance when it is connected to VL. MODE is internally pulled to GND by a $10\Omega$ resistor for $0.1\mu s$ (typ) when the high-voltage switch-control block is enabled.    |
| 8      | DLP   | GON Output Enable. See the <i>High-Voltage Switch Control</i> section for details.  |
| 9      | FBP   | Positive Charge-Pump Regulator Feedback Input. Connects FBP to the center of a resistive voltage-divider between the positive charge-pump regulator output and AGND to set the positive charge-pump regulator output voltage. Place the resistive voltage-divider within 5mm of FBP.  |
| 10     | CPGND | Charge Pump and Internal Step-Down Regulator Pulldown Switch Power Ground   |
| 11     | CTL   | High-Voltage Switch-Control Block Timing Control Input. See the <i>High-Voltage Switch Control</i> section  |
| 12     | DRVVN | Negative Charge-Pump Driver Output. Connects DRVVN to the negative charge-pump flying capacitor(s).   |
| 13, 40 | AGND  | Analog Ground   |
| 14     | FBN   | Negative Charge-Pump Regulator Feedback Input. Connects FBN to the center of a resistive voltage-divider between the negative output and REF to set the negative charge-pump regulator output voltage. Place the resistive voltage-divider within 5mm of FBN.   |
| 15     | REF   | Reference Output. Connects a $0.22\mu F$ capacitor from REF to AGND. All power outputs are disabled until REF exceeds its UVLO threshold. REF is active whenever $V_{IN}$ is above its UVLO threshold.  |
| 16     | DEL1  | Negative Charge-Pump Delay Input. Connects a capacitor from DEL1 and AGND to set the delay time between the step-down output and the negative output. An $8\mu A$ current source charges $C_{DEL1}$ . DEL1 is internally pulled to AGND through $10\Omega$ resistance when EN1 is low or VL is below its UVLO threshold.                        |
| 17     | FB2   | Step-Down Regulator Feedback Input. Connects FB2 to GND to select the step-down converter's 3.3V fixed mode. For adjustable mode, connect FB2 to the center of a resistive voltage-divider between the step-down regulator output and GND to set the step-down regulator output voltage. Place the resistive voltage-divider within 5mm of FB2. |
| 18     | BST   | Step-Down Regulator Bootstrap Capacitor Connection for High-Side Gate Driver. Connects a $0.1\mu F$ ceramic capacitor from BST to LX2.  |
| 19, 20 | LX2   | Step-Down Regulator Switching Node. LX2 is the source of the internal n-channel MOSFET connected between IN2 and LX2. Connect the inductor and Schottky catch diode to both LX2 pins to minimize the trace area for low EMI.  |
| 21     | OUT   | Step-Down Regulator Output-Voltage Sense Input. Connects OUT to the step-down regulator output.   |
| 22, 23 | IN2   | Step-Down Regulator Power Input. Drain of the internal n-channel MOSFET connected between IN2 and LX2.  |
| 24     | VIN   | Input of the Internal 5V Linear Regulator and the Startup Circuitry. Bypass VIN to AGND with $0.22\mu F$ close to the IC.   |

# Low-Cost, Multiple-Output Power Supply for LCD TVs

## Pin Description (continued)

| PIN    | NAME  | FUNCTION  |
|--------|-------|---|
| 25     | FSEL  | Frequency Select Pin. Connect FSEL to AGND for 450kHz operation. Connect to VL or VIN for 600kHz operation.   |
| 26     | EN1   | Step-Down and Negative Charge-Pump Regulator Enable Input. Input high also enables DLY1 pullup current.   |
| 27     | DEL2  | Step-Up Regulator and Positive Charge-Pump Delay Input. Connects a capacitor from DEL2 and AGND to set the delay time between EN2 and the startup of these regulators, or between the step-down startup and the startup of these regulators if EN1 is high before the step-down starts. An 8 $\mu$ A current source charges C <sub>DEL2</sub> . DEL2 is internally pulled to AGND through 10 $\Omega$ resistance when EN1 or EN2 is low or when VL is below its UVLO threshold. |
| 28     | VL    | 5V Internal Linear Regulator Output. Bypass VL to AGND with 1 $\mu$ F minimum. Provides power for the internal MOSFET driving circuit, the PWM controllers, charge-pump regulators, logic, and reference and other analog circuitry. Provides 25mA load current when all switching regulators are enabled. VL is active whenever V <sub>IN</sub> is above its UVLO threshold.   |
| 29     | EN2   | Step-Up and Positive Charge-Pump Regulator Enable Input. Input high also enables DLY2 pullup current. EN2 is inactive when EN1 is low.  |
| 30, 31 | PGND  | Step-Up Regulator Power Ground. Source of the internal power n-channel MOSFET.  |
| 32, 33 | LX1   | Step-Up Regulator Power MOSFET n-Channel Drain and Switching Node. Connects the inductor and Schottky catch diode to both LX1 pins and minimize the trace area for the lowest EMI.  |
| 34     | SWI   | Step-Up Regulator Internal PMOS Pass Switch Source Input. Connects to the anode of the step-up regulator Schottky catch diode.  |
| 35     | SWO   | Step-Up Regulator Internal pMOS Pass Switch Drain Output  |
| 36     | FB1   | Boost Regulator Feedback Input. Connects FB1 to the center of a resistive voltage-divider between the boost regulator output and AGND to set the boost regulator output voltage. Place the resistive voltage-divider within 5mm of FB1.   |
| 37     | COMP  | Compensation Pin for the Step-Up Error Amplifier. Connects a series resistor and capacitor from COMP to AGND.   |
| 38     | PGOOD | Open-Drain Power-Good Output. Monitors the step-down output voltage.  |
| 39     | CRST  | Power-Good Reset Timing Pin. Connects a capacitor from CRST to AGND to set the step-down output-rising PGOOD delay.   |
| —      | EP    | Exposed Pad = AGND  |

# Low-Cost, Multiple-Output Power Supply for LCD TVs

MAX17113

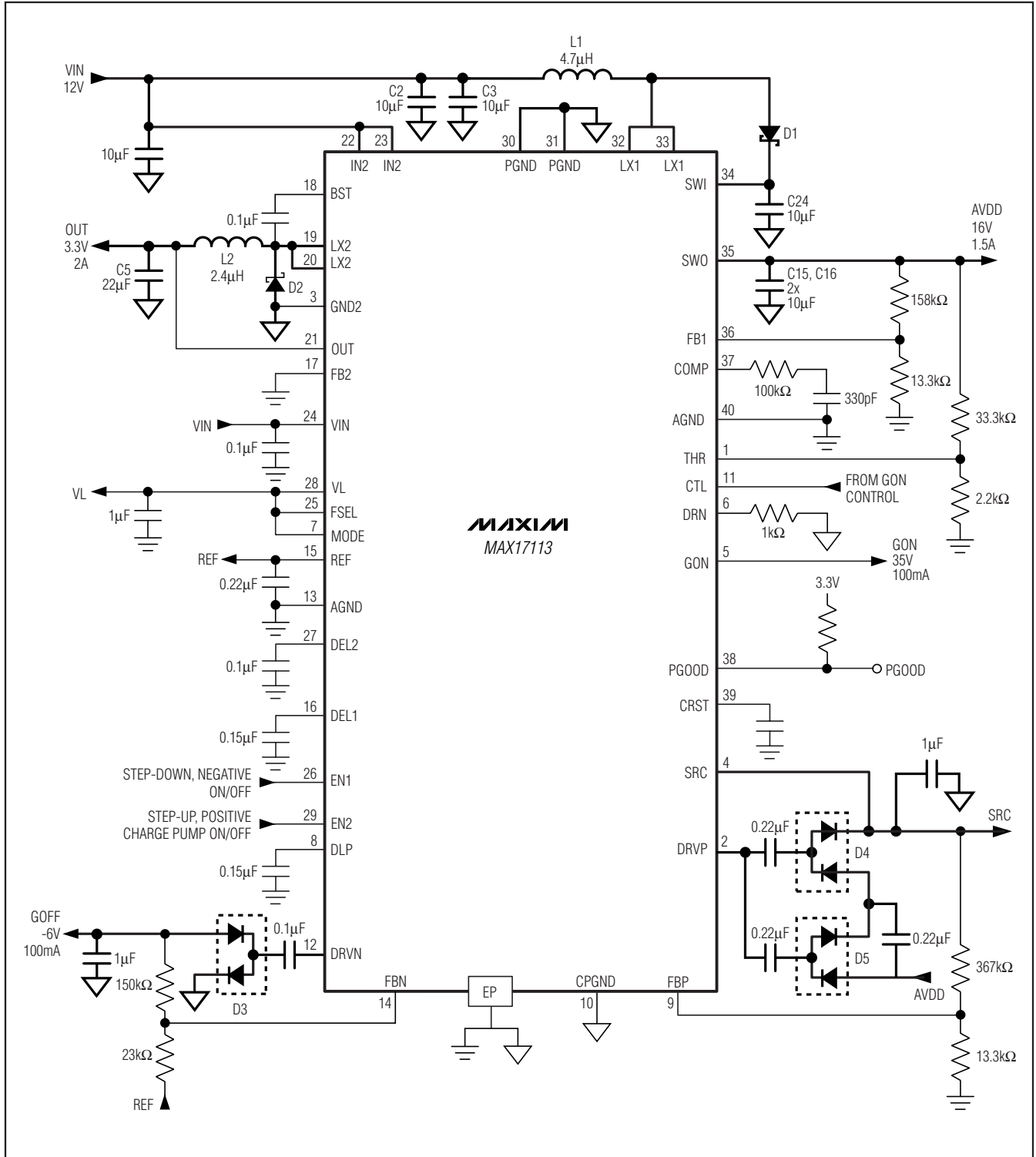


Figure 1. Typical Operating Circuit

# Low-Cost, Multiple-Output Power Supply for LCD TVs

## Typical Operating Circuit

The typical operating circuit (Figure 1) of the MAX17113 is a complete power-supply system for TFT LCD panels in monitors and TVs. The circuit generates a +3.3V logic supply, a +16V source driver supply, a +34.5V positive gate driver supply, and a -6V negative gate driver supply from a 12V  $\pm$ 10% input supply. Table 1 lists some selected components and Table 2 lists the contact information for component suppliers.

**Table 1. Component List**

| DESIGNATION   | DESCRIPTION  |
|---------------|--|
| C1, C2, C3    | 10 $\mu$ F $\pm$ 20%, 16V X5R ceramic capacitors (1206)<br>Taiyo Yuden EMK325BJ106MD<br>TDK C3225X7R1C106M                                   |
| C5            | 22 $\mu$ F $\pm$ 10%, 6.3V X5R ceramic capacitor (1206)<br>Taiyo Yuden JMK316BJ226KL<br>Murata GRM31CR60J226M                                |
| C15, C16, C24 | 10 $\mu$ F $\pm$ 20%, 25V X5R ceramic capacitors (1210)<br>TDK C3225X5R1E106M  |
| D1, D2        | 3A, 30V Schottky diodes (M-Flat)<br>Toshiba CMS02 (TE12L,Q)<br>Central Semiconductor   |
| D3, D4, D5    | 200mA, 100V dual ultra-fast diodes (SOT23)<br>Fairchild MMBD4148SE (top mark D4)<br>Central Semiconductor CMPD1001S lead free (top mark L21) |
| L1            | Low-profile 4.7 $\mu$ H, 3.5A inductor (2mm height)<br>TOKO FDV0620-4R7M   |
| L2            | Low-profile 2.4 $\mu$ H, 2.6A inductor (1.8mm height)<br>TOKO 1124BS-2R4M (2.4 $\mu$ H)<br>Würth 744052002 (2.5 $\mu$ H)                     |

**Table 2. Component Suppliers**

| SUPPLIER                                    | PHONE        | FAX          | WEBSITE               |
|---|--------------|--------------|-----------------------|
| Fairchild Semiconductor                     | 408-822-2000 | 408-822-2102 | www.fairchildsemi.com |
| Sumida Corp.                                | 847-545-6700 | 847-545-6720 | www.sumida.com        |
| TDK Corp.                                   | 847-803-6100 | 847-390-4405 | www.component.tdk.com |
| Toshiba America Electronic Components, Inc. | 949-455-2000 | 949-859-3963 | www.toshiba.com/taec  |

## Detailed Description

The MAX17113 is a multiple-output power supply designed primarily for TFT LCD panels used in monitors and TVs. It contains a step-down switching regulator to generate the logic supply rail, a step-up switching regulator to generate the source driver supply, and two charge-pump regulators to generate the gate driver supplies. Each regulator features adjustable output voltage, digital soft-start, and timer-delayed fault protection. Both the step-down and step-up regulators use a fixed-frequency current-mode control architecture. The two switching regulators are 180° out-of-phase to minimize the input ripple. The internal oscillator offers two pin-selectable frequency options (450kHz/600kHz), allowing users to optimize their designs based on the specific application requirements. In addition, the MAX17113 features a high-voltage switch-control block, a PGOOD logic block, an internal 5V linear regulator, a 1.25V reference output, well-defined power-up and power-down sequences, and thermal-overload protection. Figure 2 shows the MAX17113 functional diagram.

### Step-Down Regulator

The step-down regulator consists of an internal n-channel MOSFET with gate driver, a lossless current-sense network, a current-limit comparator, and a PWM controller block. The external power stage consists of a Schottky diode rectifier, an inductor, and output capacitors. The output voltage is regulated by changing the duty cycle of the n-channel MOSFET. A bootstrap circuit that uses a 0.1 $\mu$ F flying capacitor between LX2 and BST provides the supply voltage for the high-side gate driver. Although the MAX17113 also includes a 10 $\Omega$  (typ) low-side MOSFET, this switch is used to charge the bootstrap capacitor during startup and maintains fixed-frequency operation at light load and cannot be used as a synchronous rectifier. An external Schottky diode (D2 in Figure 1) is always required.

# Low-Cost, Multiple-Output Power Supply for LCD TVs

MAX17113

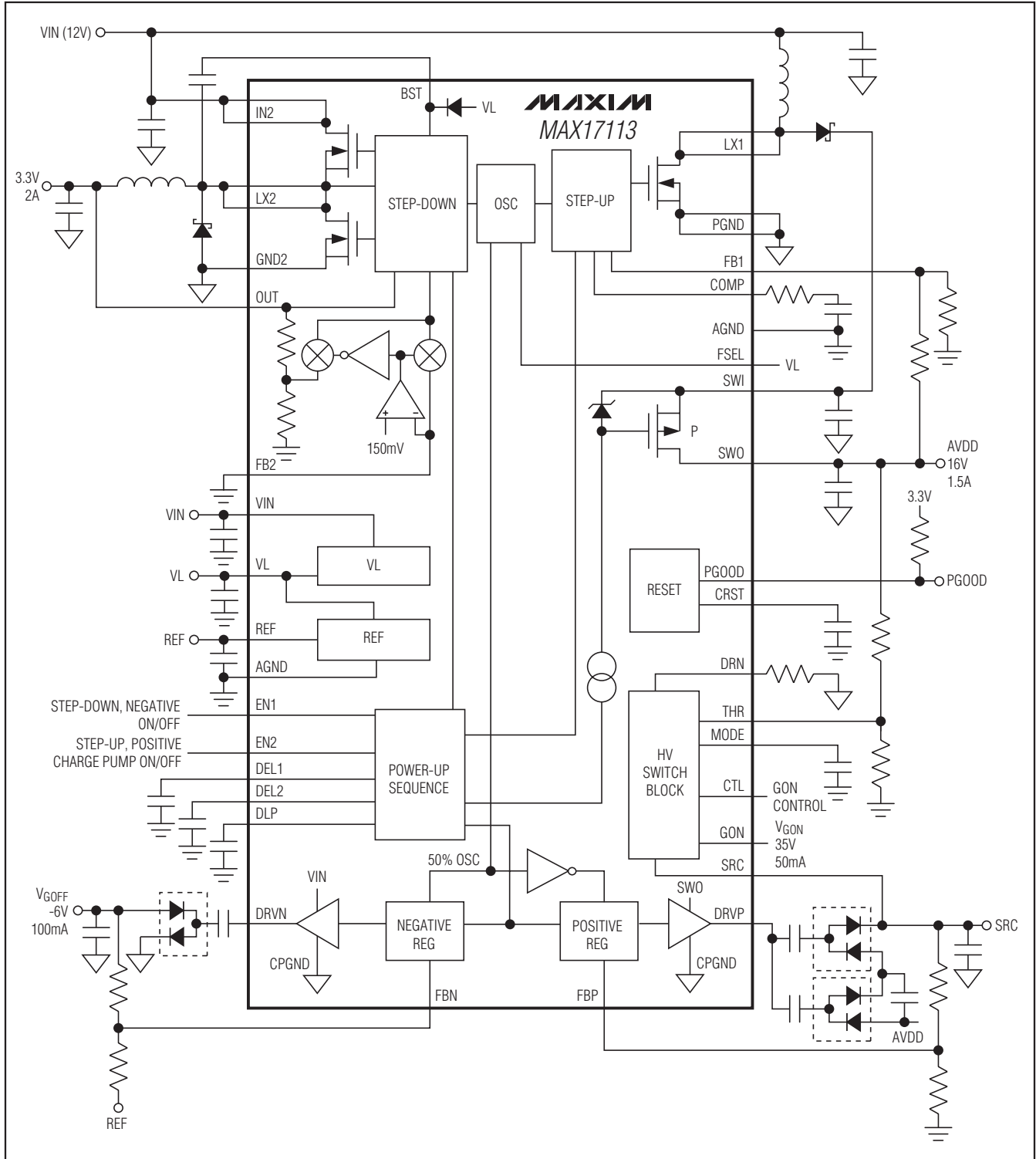


Figure 2. Functional Diagram

# Low-Cost, Multiple-Output Power Supply for LCD TVs

## PWM Controller Block

The heart of the PWM control block is a multi-input, open-loop comparator that sums three signals: the output-voltage signal with respect to the reference voltage, the current-sense signal, and the slope compensation. The PWM controller is a direct-summing type, lacking a traditional error amplifier and the phase shift associated with it. This direct-summing configuration approaches ideal cycle-by-cycle control over the output voltage.

When EN1 and EN2 are high, the controller always operates in fixed-frequency PWM mode. Each pulse from the oscillator sets the main PWM latch that turns on the high-side switch until the PWM comparator changes state.

When EN1 is high and EN2 is low, the controller operates in skip mode. The skip mode dramatically improves light-load efficiency by reducing the effective frequency, which reduces switching losses. It keeps the peak inductor current at about 0.9A (typ) in an active cycle, allowing subsequent cycles to be skipped. Skip mode transitions seamlessly to fixed-frequency PWM operation as load current increases.

## Current Limiting and Lossless Current Sensing

The current-limit circuit turns off the high-side MOSFET switch whenever the voltage across the high-side MOSFET exceeds an internal threshold. The actual current limit is 3A (typ).

For current-mode control, an internal lossless sense network derives a current-sense signal from the inductor DCR. The time constant of the current-sense network is not required to match the time constant of the inductor and has been chosen to provide sufficient current ramp signal for stable operation at both operating frequencies. The current-sense signal is AC-coupled into the PWM comparator, eliminating most DC output-voltage variation with load current.

## Low-Frequency Operation

The step-down regulator of the MAX17113 enters into low-frequency operating mode if the voltage on OUT is below 0.8V. In the low-frequency mode, the switching frequency of the step-down regulator is 1/6 the oscillator frequency. This feature prevents potentially uncontrolled inductor current if OUT is overloaded or shorted to ground.

## Dual-Mode Feedback

The step-down regulator of the MAX17113 supports both fixed and adjustable output voltages. Connect FB2 to AGND to enable the 3.3V fixed output voltage. Connect a resistive voltage-divider between OUT and

AGND with the center tap connected to FB2 to adjust the output voltage. Choose RB (resistance from FB2 to AGND) to be between 5k $\Omega$  and 50k $\Omega$ , and solve for RA (resistance from OUT1 to FB1) using the equation:

$$RA = RB \times \left( \frac{V_{OUT}}{V_{FB2}} - 1 \right)$$

where  $V_{FB2} = 1.25V$ , and  $V_{OUT}$  can vary from 1.25V to 5V.

Because of FB2's (pin 17) close proximity to the noisy BST (pin 18), a noise filter is required for FB2 adjustable-mode operation. Place a 100pF capacitor from FB2 to AGND to prevent unstable operation. No filter is required for 3.3V fixed-mode operation.

## Soft-Start

The step-down regulator includes a 7-bit soft-start DAC that steps its internal reference voltage from 0 to 1.25V in 128 steps. The soft-start period is 3ms (typ) and FB2 fault detection is disabled during this period. The soft-start feature effectively limits the inrush current during startup (see the Step-Down Regulator Soft-Start (Heavy Load) waveforms in the *Typical Operating Characteristics*).

## Step-Up Regulator

The step-up regulator employs a current-mode, fixed-frequency PWM architecture to maximize loop bandwidth and provide fast-transient response to pulsed loads typical of TFT LCD panel source drivers. The integrated MOSFET and the built-in digital soft-start function reduce the number of external components required while controlling inrush currents. The output voltage can be set from  $V_{IN}$  to 20V with an external resistive voltage-divider. The regulator controls the output voltage and the power delivered to the output by modulating the duty cycle (D) of the internal power MOSFET in each switching cycle. The duty cycle of the MOSFET is approximated by:

$$D \approx \frac{V_{AVDD} - V_{IN}}{V_{AVDD}}$$

where  $V_{AVDD}$  is the output voltage of the step-up regulator.

## PWM Controller Block

An error amplifier compares the signal at FB1 to 1.25V and changes the COMP output. The voltage at COMP sets the peak inductor current. As the load varies, the error amplifier sources or sinks current to the COMP output accordingly to produce the inductor peak current necessary to service the load. To maintain stability at high duty cycles, a slope compensation signal is summed with the current-sense signal.

# Low-Cost, Multiple-Output Power Supply for LCD TVs

On the rising edge of the internal clock, the controller sets a flip-flop, turning on the n-channel MOSFET and applying the input voltage across the inductor. The current through the inductor ramps up linearly, storing energy in its magnetic field. Once the sum of the current-feedback signal and the slope compensation exceed the COMP voltage, the controller resets the flip-flop and turns off the MOSFET. Since the inductor current is continuous, a transverse potential develops across the inductor that turns on the diode (D1). The voltage across the inductor then becomes the difference between the output voltage and the input voltage. This discharge condition forces the current through the inductor to ramp back down, transferring the energy stored in the magnetic field to the output capacitor and the load. The MOSFET remains off for the rest of the clock cycle.

### Step-Up Regulator Internal p-Channel MOSFET Pass Switch

The MAX17113 includes an integrated 130mΩ high-voltage p-channel MOSFET to allow true shutdown of the step-up converter output (AVDD). This switch is typically connected in series between the step-up regulator's Schottky catch diode and its output capacitors. In addition to allowing step-up output to discharge completely when disabled, this switch also controls the startup inrush current into the step-up regulator's output capacitors.

### Soft-Start

The step-up regulator includes a 7-bit soft-start DAC that steps its internal reference voltage from 0 to 1.25V

in 128 steps. This DAC also controls linearly the gate of the pMOS switch, which is in between SWI and SWO, and the output AVDD goes up smoothly, and when the AVDD reaches the input voltage, the step-up regulator takes over seamlessly and the output-voltage AVDD reaches its regulation point. The soft-start period is 10ms (typ) and FB1 fault detection is disabled during this period. The soft-start feature effectively limits the inrush current during startup.

### Positive Charge-Pump Regulator

The positive charge-pump regulator is typically used to generate the positive supply rail for the TFT LCD gate driver ICs. The output voltage is set with an external resistive voltage-divider from its output to GND with the midpoint connected to FBP. The number of charge-pump stages and the setting of the feedback divider determine the output voltage of the positive charge-pump regulator. The charge pump includes a high-side p-channel MOSFET (P1) and a low-side n-channel MOSFET (N1) to control the power transfer as shown in Figure 3.

During the first half-cycle, N1 turns on and charges flying capacitors C20 and C21 (Figure 3). During the second half cycle, N1 turns off and P1 turns on, level shifting C20 and C21 by  $V_{AVDD}$  volts. If the voltage across C23 plus a diode drop ( $V_{OUT} + V_D$ ) is smaller than the level-shifted flying capacitor voltage ( $V_{C20} + V_{AVDD}$ ), charge flows from C20 to C23 until the diode (D5) turns off. The amount of charge transferred to the output is determined by the error amplifier that controls N1's on-resistance.

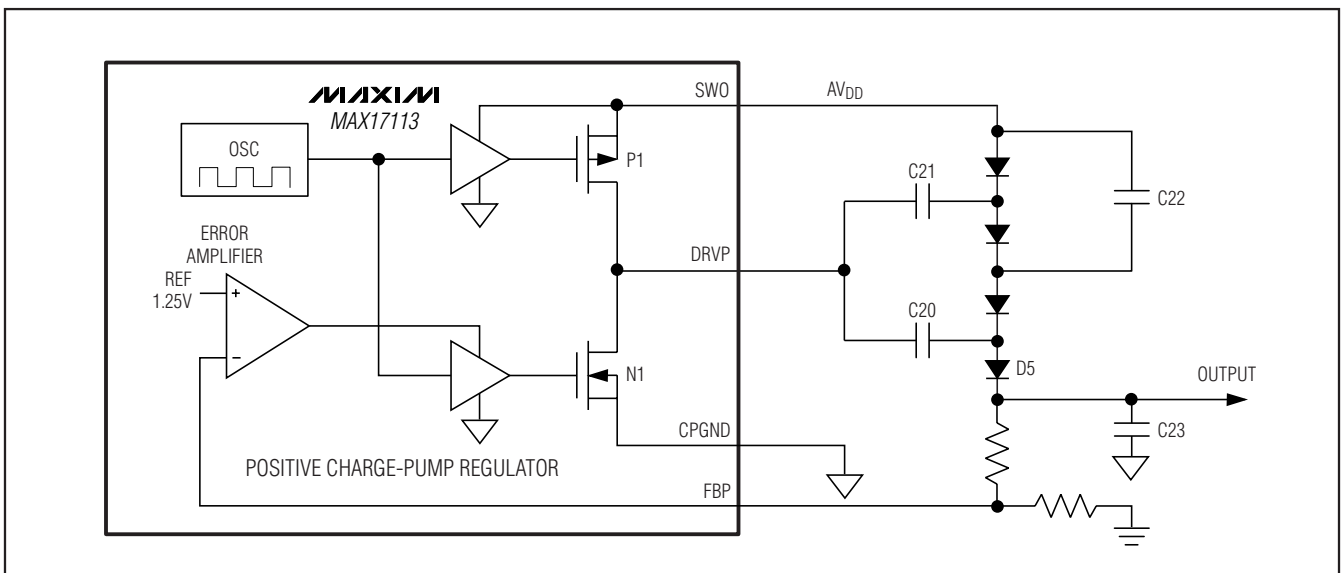


Figure 3. Positive Charge-Pump Regulator Block Diagram

## Low-Cost, Multiple-Output Power Supply for LCD TVs

The positive charge-pump regulator's startup can be delayed by connecting an external capacitor from DEL2 to AGND. An internal constant-current source begins charging the DEL2 capacitor when EN2 is logic-high, and the step-down regulator reaches regulation. When the DEL2 voltage exceeds  $V_{REF}$ , the positive charge-pump regulator is enabled. Each time it is enabled, the positive charge-pump regulator goes through a soft-start routine by ramping up its internal reference voltage from 0 to 1.25V in 128 steps. The soft-start period is 3ms (typ) and FBP fault detection is disabled during this period. The soft-start feature effectively limits the inrush current during startup.

### Negative Charge-Pump Regulator

The negative charge-pump regulator is typically used to generate the negative supply rail for the TFT LCD gate driver ICs. The output voltage is set with an external resistive voltage-divider from its output to REF with the midpoint connected to FBN. The number of charge-pump stages and the setting of the feedback divider determine the output of the negative charge-pump regulator. The charge-pump controller includes a high-side p-channel MOSFET (P2) and a low-side n-channel MOSFET (N2) to control the power transfer as shown in Figure 4.

During the first half cycle, P2 turns on, and flying capacitor C13 charges to  $V_{IN}$  minus a diode drop (Figure 4). During the second half cycle, P2 turns off, and N2 turns on, level shifting C13. This connects C13 in parallel with reservoir capacitor C12. If the voltage across C12 minus a diode drop is greater than the voltage across C13, charge flows from C12 to C13 until the diode (D3) turns off. The amount of charge transferred from the output is determined by the error amplifier, which controls N2's on-resistance.

The negative charge-pump regulator is enabled when EN1 is logic-high and the step-down regulator reaches regulation. Each time it is enabled, the negative charge-pump regulator goes through a soft-start routine by ramping down its internal reference voltage from 1.25V to 250mV in 102 steps. The soft-start period is 3ms (typ) and FBN fault detection is disabled during this period. The soft-start feature effectively limits the inrush current during startup.

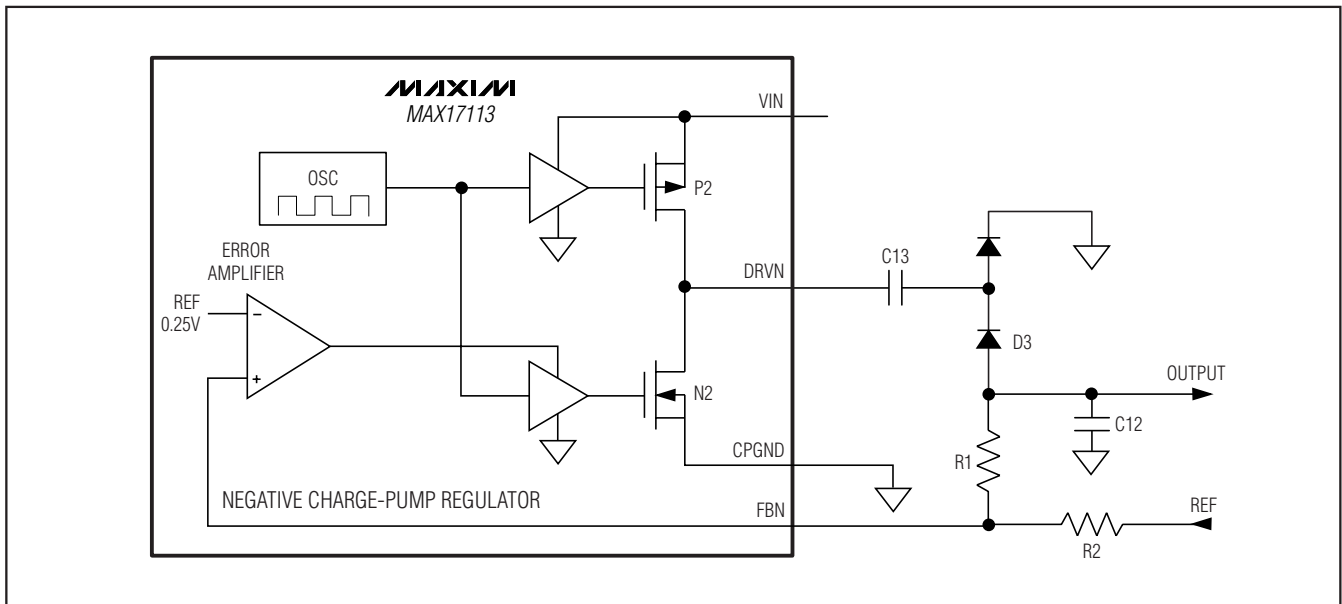


Figure 4. Negative Charge-Pump Regulator Block Diagram

# Low-Cost, Multiple-Output Power Supply for LCD TVs

MAX17113

## High-Voltage Switch Control

The MAX17113's high-voltage switch control block (Figure 5) consists of two high-voltage p-channel MOSFETs: Q1, between SRC and GON and Q2, between GON and DRN. The switch control block is enabled when  $V_{DLP}$  exceeds  $V_{REF}$ . Q1 and Q2 are controlled by CTL and MODE. There are two different modes of operation (see the *Typical Operating Characteristics*).

Select the first mode by connecting MODE to VL. When CTL is logic-high, Q1 turns on and Q2 turns off, connecting GON to SRC. When CTL is logic-low, Q1 turns off and Q2 turns on, connecting GON to DRN. GON can then be discharged through a resistor connected between DRN and GND or  $AV_{DD}$ . Q2 turns off and stops discharging GON when  $V_{GON}$  reaches 10 times the voltage on THR.

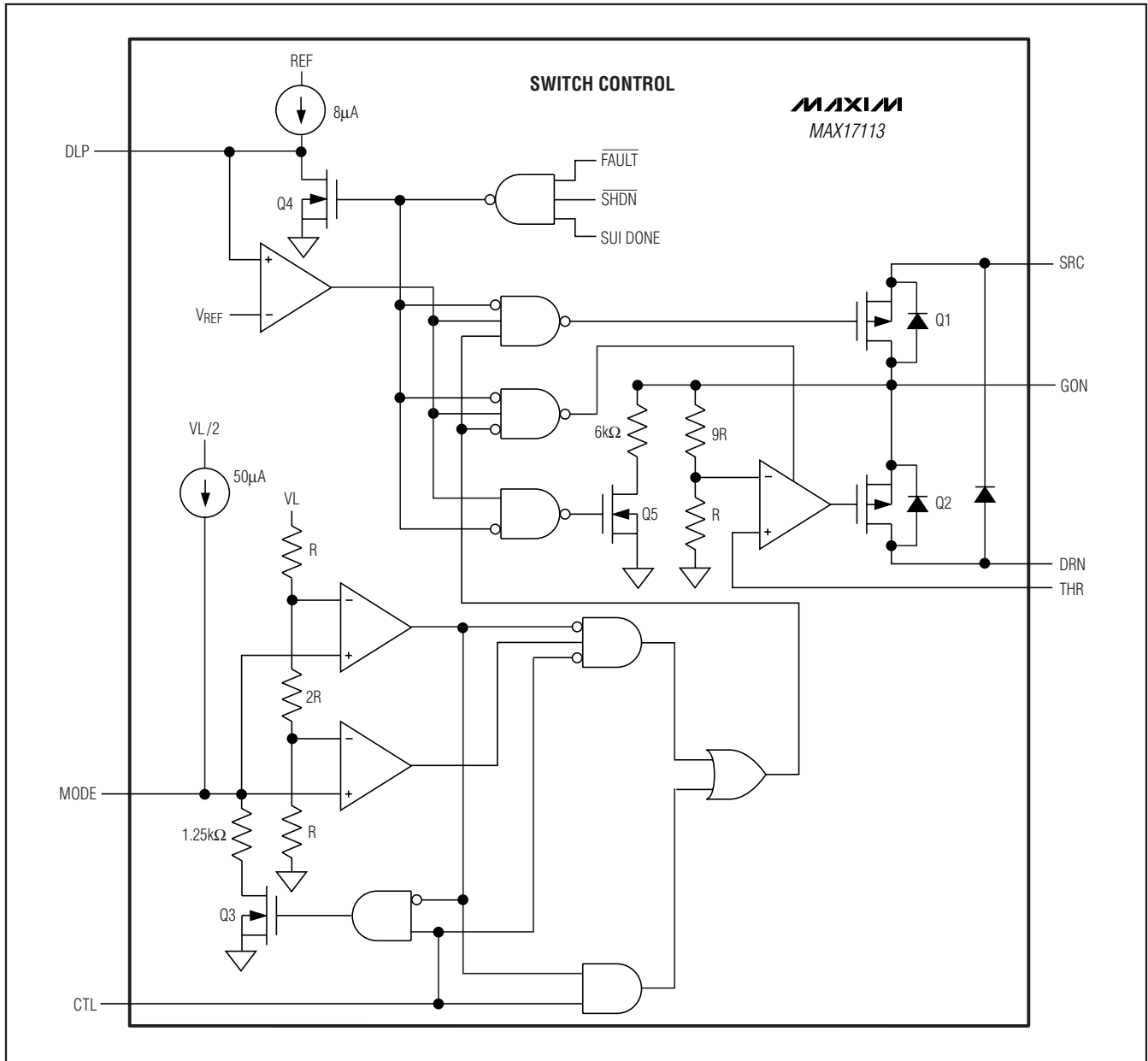


Figure 5. Switch Control

# Low-Cost, Multiple-Output Power Supply for LCD TVs

When  $V_{MODE}$  is less than  $0.8 \times V_{VL}$ , the switch control block works in the second mode. The rising edge of  $V_{CTL}$  turns on Q1 and turns off Q2, connecting GON to SRC. An internal n-channel MOSFET, Q3, between MODE and AGND is also turned on to discharge an external capacitor between MODE and AGND. The falling edge of  $V_{CTL}$  turns off Q3, and an internal  $50\mu A$  current source starts charging the MODE capacitor. Once  $V_{MODE}$  exceeds  $V_{VL}/4$ , the switch control block turns off Q1 and turns on Q2, connecting GON to DRN. GON can then be discharged through a resistor connected between DRN and PGND or AVDD. Q2 turns off and stops discharging GON when  $V_{GON}$  reaches 10 times the voltage on THR.

The switch control block is disabled and DLP is held low when EN1 or EN2 is low or the IC is in a fault state.

## Linear Regulator (VL)

The MAX17113 includes an internal linear regulator. VIN is the input of the linear regulator. The input voltage range is between 8V and 16.5V. The output voltage is set to 5V. The regulator powers the internal MOSFET drivers, PWM controllers, charge-pump regulators, and logic circuitry. The total external load capability is 25mA. Bypass VL to AGND with a minimum  $1\mu F$  ceramic capacitor.

## Reference Voltage (REF)

The reference output is nominally 1.25V, and can source at least  $50\mu A$  (see the *Typical Operating Characteristics*). VL is the input of the internal reference block. Bypass REF with a  $0.22\mu F$  ceramic capacitor connected between REF and AGND.

## Frequency Selection (FSEL)

The step-down regulator and step-up regulator use the same internal oscillator. The FSEL input selects the switching frequency. Table 3 shows the switching frequency based on the FSEL connection. High-frequency (600kHz) operation optimizes the application for the smallest component size, trading off efficiency due to higher switching losses. Low-frequency (450kHz) operation offers the best overall efficiency at the expense of component size and board space.

**Table 3. Frequency Selection**

| FSEL | SWITCHING FREQUENCY (kHz) |
|------|---------------------------|
| VIN  | 600                       |
| AGND | 450                       |

## Power-Up Sequence

The step-down regulator starts up when the MAX17113's internal reference voltage (REF) is above its undervoltage lockout (UVLO) threshold and EN1 is logic-high.

Once the step-down regulator reaches regulation, the FB2 fault-detection circuit and the negative charge-pump delay block are enabled. An  $8\mu A$  current source at DEL1 charges  $C_{DEL1}$  linearly. The negative charge-pump regulator soft-starts when  $V_{DEL1}$  reaches  $V_{REF}$ . FBN fault detection is enabled once the negative charge-pump soft-start is done. See Figure 6.

The step-up regulator, p-channel MOSFET pass switch, and positive charge-pump startup sequence begin when the step-down regulator reaches regulation and EN2 is logic-high. An  $8\mu A$  current source at DEL2 charges  $C_{DEL2}$  linearly and the positive charge pump is enabled when  $V_{DEL2}$  reaches  $V_{REF}$ . When the positive charge pump is in regulation, an  $8\mu A$  current source charges  $C_{DLP}$  linearly and when  $V_{DLP}$  reaches  $V_{REF}$ , the high-voltage switch is enabled and GON can be controlled by CTL.

The FB1 fault-detection circuit is enabled after the step-up regulator reaches regulation, and similarly the FBP fault-detection circuit is enabled after the positive charge pump reaches regulation. For nondelayed startups, capacitors can be omitted from DEL1, DEL2, and DLP. When their current sources pull the pins above their thresholds, the associated outputs start.

## Power-Down Control

The MAX17113 disables the step-up regulator, positive-charge-pump regulator input switch control block, delay block, and high-voltage switch control block when EN2 is logic-low, or when the fault latch is set. The step-down regulator and negative charge-pump regulator are disabled only when EN1 is logic-low or when the fault latch is set.

## Fault Protection

During steady-state operation, if any output of the four regulators (step-down regulator, step-up regulator, positive charge-pump regulator, and negative charge-pump regulator) does not exceed its respective fault-detection threshold, the MAX17113 activates an internal fault timer. If any condition or the combination of conditions indicates a continuous fault for the fault timer duration (50ms, typ), the MAX17113 triggers a non-latching output undervoltage fault. After triggering, the MAX17113 turns off for 160ms (typ) and then restarts according to the EN1 and EN2 logic states. If, after restarting, another 50ms fault timeout occurs, the MAX17113 shuts down for 160ms again, and then restarts. The restart sequence is repeated 3 times and after the 50ms fault timeout, the MAX17113 shuts down and latches off. Once the fault condition is removed, toggle either EN1 or EN2, or cycle the input voltage to clear the fault latch and restart the supplies.

# Low-Cost, Multiple-Output Power Supply for LCD TVs

MAX17113

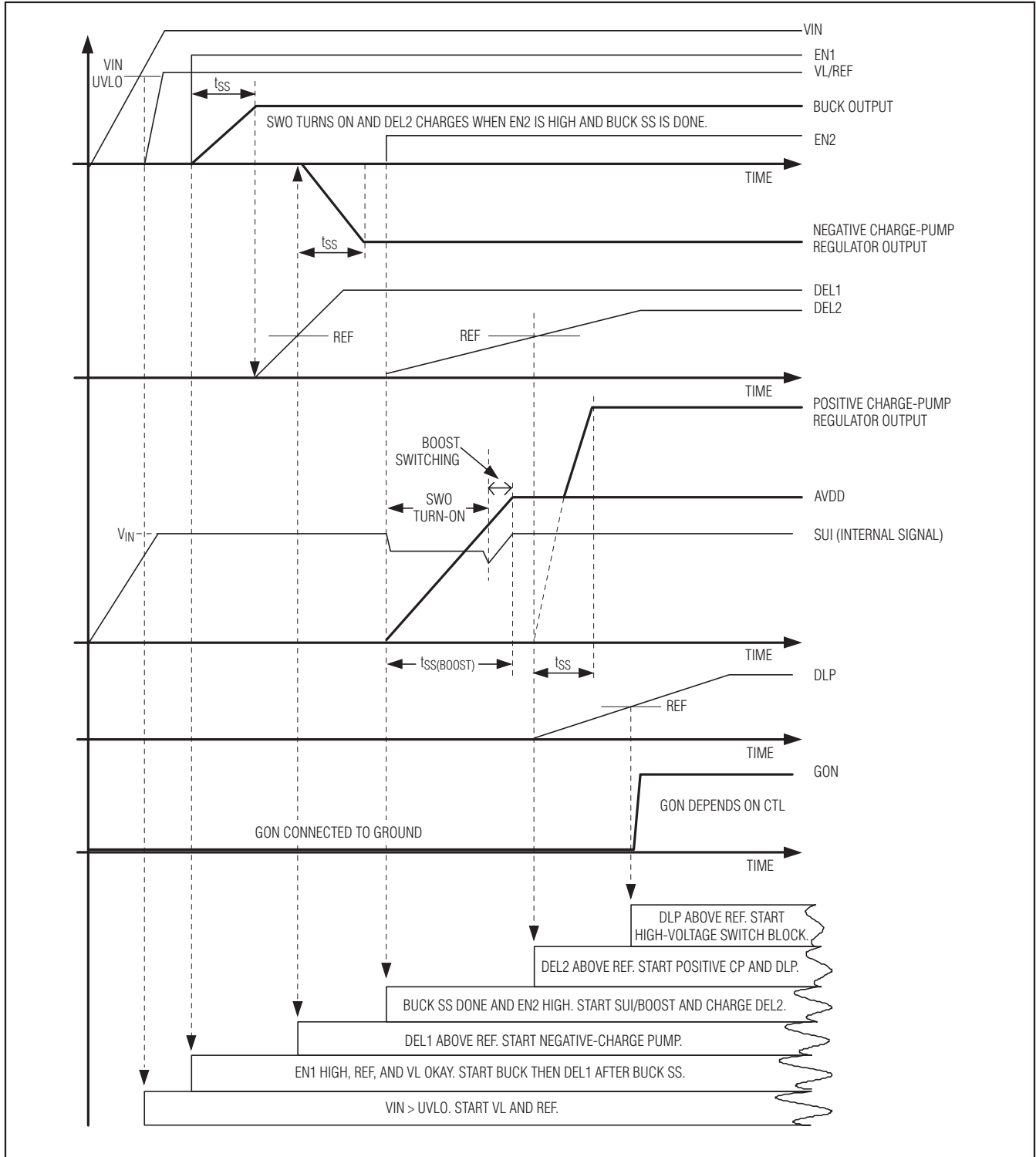


Figure 6. Startup Sequence

# Low-Cost, Multiple-Output Power Supply for LCD TVs

## Thermal-Overload Protection

The thermal-overload protection prevents excessive power dissipation from overheating the MAX17113. When the junction temperature exceeds  $T_J = +160^\circ\text{C}$ , a thermal sensor immediately activates the fault protection that shuts down all the outputs except the reference and latches off, allowing the device to cool down. Once the device cools down by at least approximately  $15^\circ\text{C}$ , cycle the input voltage to clear the fault latch and restart the MAX17113.

The thermal-overload protection protects the controller in the event of fault conditions. For continuous operation, do not exceed the absolute maximum junction temperature rating of  $T_J = +150^\circ\text{C}$ .

## Design Procedure

### Step-Down Regulator

#### Inductor Selection

Three key inductor parameters must be specified: inductance value (L), peak current ( $I_{\text{PEAK}}$ ), and DC resistance ( $R_{\text{DC}}$ ). The following equation includes a constant, LIR, which is the ratio of peak-to-peak inductor ripple current to DC load current. A higher LIR value allows smaller inductance, but results in higher losses and higher ripple. A good compromise between size and losses is typically found at about 20% to 50% ripple-current to load-current ratio (LIR):

$$L_{\text{OUT}} = \frac{V_{\text{OUT}} \times (V_{\text{IN2}} - V_{\text{OUT}})}{V_{\text{IN2}} \times f_{\text{SW}} \times I_{\text{OUT(MAX)}} \times \text{LIR}}$$

where  $I_{\text{OUT(MAX)}}$  is the maximum DC load current, and the switching frequency  $f_{\text{SW}}$  is 600kHz when FSEL is connected to VL or 450kHz when FSEL is connected to AGND. The exact inductor value is not critical and can be adjusted to make trade-offs among size, cost, and efficiency. Lower inductor values minimize size and cost, but they also increase the output ripple and reduce the efficiency due to higher peak currents. On the other hand, higher inductor values increase efficiency, but at some point resistive losses due to extra turns of wire exceed the benefit gained from lower AC current levels.

The inductor's saturation current must exceed the peak inductor current. The peak current can be calculated by:

$$I_{\text{OUT\_RIPPLE}} = \frac{V_{\text{OUT}} \times (V_{\text{IN2}} - V_{\text{OUT}})}{f_{\text{SW}} \times L_{\text{OUT}} \times V_{\text{IN2}}}$$

$$I_{\text{OUT\_PEAK}} = I_{\text{OUT(MAX)}} + \frac{I_{\text{OUT\_RIPPLE}}}{2}$$

The inductor's DC resistance should be low for good efficiency. Find a low-loss inductor having the lowest possible DC resistance that fits in the allotted dimensions. Ferrite cores are often the best choice. Shielded-core geometries help keep noise, EMI, and switching waveform jitter low.

Considering the typical operating circuit in Figure 1, the maximum load current ( $I_{\text{OUT(MAX)}}$ ) is 2A with a 3.3V output and a typical 12V input voltage. Choosing an LIR of 0.4 at this operating point:

$$L_{\text{OUT}} = \frac{3.3\text{V} \times (12\text{V} - 3.3\text{V})}{12\text{V} \times 600\text{kHz} \times 2\text{A} \times 0.4} \approx 5.0\mu\text{H}$$

At that operating point, the ripple current and the peak current are:

$$I_{\text{OUT\_RIPPLE}} = \frac{3.3\text{V} \times (12\text{V} - 3.3\text{V})}{600\text{kHz} \times 5.0\mu\text{H} \times 12} \approx 0.8\text{A}$$

$$I_{\text{OUT\_PEAK}} = 2\text{A} + \frac{0.8\text{A}}{2} = 2.4\text{A}$$

#### Input Capacitors

The input filter capacitors reduce peak currents drawn from the power source and reduce noise and voltage ripple on the input caused by the regulator's switching. They are usually selected according to input ripple current requirements and voltage rating, rather than capacitance value. The input voltage and load current determine the RMS input ripple current ( $I_{\text{RMS}}$ ):

$$I_{\text{RMS}} = I_{\text{OUT}} \times \frac{\sqrt{V_{\text{OUT}} \times (V_{\text{IN2}} - V_{\text{OUT}})}}{V_{\text{IN2}}}$$

The worst case is  $I_{\text{RMS}} = 0.5 \times I_{\text{OUT}}$ , which occurs at  $V_{\text{IN2}} = 2 \times V_{\text{OUT}}$ .

For most applications, ceramic capacitors are used because of their high ripple current and surge current capabilities. For optimal circuit long-term reliability, choose an input capacitor that exhibits less than  $+10^\circ\text{C}$  temperature rise at the RMS input current corresponding to the maximum load current.

#### Output Capacitor Selection

Since the MAX17113's step-down regulator is internally compensated, it is stable with any reasonable amount of output capacitance. However, the actual capacitance and equivalent series resistance (ESR) affect the regulator's output ripple voltage and transient response. The rest of this section deals with how to determine the output capacitance and ESR needs according to the ripple-voltage and load-transient requirements.

# Low-Cost, Multiple-Output Power Supply for LCD TVs

The output-voltage ripple has two components: variations in the charge stored in the output capacitor, and the voltage drop across the capacitor's ESR caused by the current into and out of the capacitor:

$$V_{OUT\_RIPPLE} = V_{OUT\_RIPPLE(ESR)} + V_{OUT\_RIPPLE(C)}$$

$$V_{OUT\_RIPPLE(ESR)} = I_{OUT\_RIPPLE} \times R_{ESR\_OUT}$$

$$V_{OUT\_RIPPLE(C)} = \frac{I_{OUT\_RIPPLE}}{8 \times C_{OUT} \times f_{SW}}$$

where  $I_{OUT\_RIPPLE}$  is defined in the *Inductor Selection* of the *Step-Down Regulator* section,  $C_{OUT}$  is the output capacitance, and  $R_{ESR\_OUT}$  is the ESR of the output capacitor  $C_{OUT}$ . In Figure 1's circuit, the inductor ripple current is 0.8A. If the voltage-ripple requirement of Figure 1's circuit is  $\pm 1\%$  of the 3.3V output, then the total peak-to-peak ripple voltage should be less than 66mV. Assuming that the ESR ripple and the capacitive ripple each should be less than 50% of the total peak-to-peak ripple, then the ESR should be less than  $43m\Omega$  and the output capacitance should be more than  $5\mu F$  to meet the total ripple requirement. A  $22\mu F$  capacitor with ESR (including PCB trace resistance) of  $10m\Omega$  is selected for the standard application circuit in Figure 1, which easily meets the voltage-ripple requirement.

The step-down regulator's output capacitor and ESR can also affect the voltage undershoot and overshoot when the load steps up and down abruptly. The step-down regulator's transient response is typically dominated by its loop response and the time constant of its internal integrator. However, excessive inductance or insufficient output capacitance can degrade the natural transient response. Calculating the ideal transient response of the inductor and capacitor, which assumes an ideal response from the regulator, can ensure that these components do not degrade the IC's natural response.

The ideal undershoot and overshoot have two components: the voltage steps caused by ESR, and the voltage sag and soar due to the finite capacitance and the inductor current slew rate. Use the following formulas to check if the ESR is low enough and the output capacitance is large enough to prevent excessive soar and sag.

The amplitude of the ESR step is a function of the load step and the ESR of the output capacitor:

$$V_{OUT\_ESR\_STEP} = \Delta I_{OUT} \times R_{ESR\_OUT}$$

The amplitude of the capacitive sag is a function of the load step, the output capacitor value, the inductor value, the input-to-output voltage differential, and the maximum duty cycle:

$$V_{OUT\_SAG} = \frac{L_{OUT} \times (\Delta I_{OUT})^2}{2 \times C_{OUT} \times (V_{IN(MIN)} \times D_{MAX} - V_{OUT})}$$

The amplitude of the capacitive soar is a function of the load step, the output capacitor value, the inductor value, and the output voltage:

$$V_{OUT\_SOAR} = \frac{L_{OUT} \times (\Delta I_{OUT})^2}{2 \times C_{OUT} \times V_{OUT}}$$

Keeping the full-load overshoot and undershoot less than 3% ensures that the step-down regulator's natural integrator response dominates. Given the component values in the circuit of Figure 1 and assuming a full 1.5A step load transient, the voltage step due to capacitor ESR is negligible. The voltage sag and soar are 76mV and 73mV, or a little over 1% and 2%, respectively.

## Rectifier Diode

The MAX17113's high switching frequency demands a high-speed rectifier. Schottky diodes are recommended for most applications because of their fast recovery time and low forward voltage. In general, a 2A Schottky diode works well in the MAX17113's step-down regulator.

## Step-Up Regulator

### Inductor Selection

The inductance value, peak current rating, and series resistance are factors to consider when selecting the inductor. These factors influence the converter's efficiency, maximum output load capability, transient response time, and output-voltage ripple. Physical size and cost are also important factors to be considered.

The maximum output current, input voltage, output voltage, and switching frequency determine the inductor value. Very high inductance values minimize the current ripple, and therefore, reduce the peak current, which decreases core losses in the inductor and  $I^2R$  losses in the entire power path. However, large inductor values also require more energy storage and more turns of wire that increase physical size and can increase  $I^2R$  losses in the inductor. Low inductance values decrease the physical size, but increase the current ripple and peak current. Finding the best inductor involves choosing the best compromise among circuit efficiency, inductor size, and cost.

The equations used here include a constant, LIR, which is the ratio of the inductor peak-to-peak ripple current to the average DC inductor current at the full-load current. The best trade-off between inductor size and circuit efficiency for step-up regulators generally has an LIR between 0.2 and 0.5. However, depending on the AC

## Low-Cost, Multiple-Output Power Supply for LCD TVs

characteristics of the inductor core material and ratio of inductor resistance to other power path resistances, the best LIR can shift up or down. If the inductor resistance is relatively high, more ripple can be accepted to reduce the number of turns required and increase the wire diameter. If the inductor resistance is relatively low, increasing inductance to lower the peak current can decrease losses throughout the power path. If extremely thin high-resistance inductors are used, as is common for smaller LCD panel applications, the best LIR can increase to between 0.5 and 1.0.

Once a physical inductor is chosen, higher and lower values of the inductor should be evaluated for efficiency improvements in typical operating regions.

Calculate the approximate inductor value using the typical input voltage ( $V_{VIN}$ ), the maximum output current ( $I_{AVDD(MAX)}$ ), the expected efficiency ( $\eta_{TYP}$ ) taken from an appropriate curve in the *Typical Operating Characteristics*, and an estimate of LIR based on the above discussion:

$$L_{AVDD} = \left( \frac{V_{VIN}}{V_{AVDD}} \right)^2 \left( \frac{V_{AVDD} - V_{VIN}}{I_{AVDD(MAX)} \times f_{SW}} \right) \left( \frac{\eta_{TYP}}{LIR} \right)$$

Choose an available inductor value from an appropriate inductor family. Calculate the maximum DC input current at the minimum input voltage  $V_{IN(MIN)}$  using conservation of energy and the expected efficiency at that operating point ( $\eta_{MIN}$ ) taken from an appropriate curve in the *Typical Operating Characteristics*:

$$I_{VIN(DC,MAX)} = \frac{I_{AVDD(MAX)} \times V_{AVDD}}{V_{VIN(MIN)} \times \eta_{MIN}}$$

Calculate the ripple current at that operating point and the peak current required for the inductor:

$$I_{AVDD\_RIPPLE} = \frac{V_{VIN(MIN)} \times (V_{AVDD} - V_{VIN(MIN)})}{L_{AVDD} \times V_{AVDD} \times f_{SW}}$$

$$I_{AVDD\_PEAK} = I_{VIN(DC,MAX)} + \frac{I_{AVDD\_RIPPLE}}{2}$$

The inductor's saturation current rating and the MAX17113's LX1 current limit should exceed  $I_{AVDD\_PEAK}$  and the inductor's DC current rating should exceed  $I_{VIN(DC,MAX)}$ . For good efficiency, choose an inductor with less than  $0.05\Omega$  series resistance.

Considering the typical operating circuit in Figure 1, the maximum load current ( $I_{AVDD(MAX)}$ ) is 1.0A with a 16V output and a typical 12V input voltage. Choosing an

LIR of 0.6 and estimating efficiency of 90% at this operating point:

$$L_{AVDD} = \left( \frac{12V}{16V} \right)^2 \left( \frac{16V - 12V}{1A \times 600kHz} \right) \left( \frac{0.90}{0.6} \right) \approx 5.6\mu H$$

Using the circuit's minimum input voltage (10.8V) and estimating efficiency of 90% at that operating point:

$$I_{VIN(DC,MAX)} = \frac{1.0A \times 16V}{10.8V \times 0.9} \approx 1.64A$$

Choosing a  $4.7\mu H$  inductor, the ripple current and the peak current are:

$$I_{RIPPLE} = \frac{10.8V \times (16V - 10.8V)}{4.7\mu H \times 16V \times 600kHz} \approx 1.2A$$

$$I_{PEAK} = 1.64A + \frac{1.2A}{2} \approx 2.24A$$

### Output Capacitor Selection

The total output-voltage ripple has two components: the capacitive ripple caused by the charging and discharging of the output capacitance, and the ohmic ripple due to the capacitor's ESR:

$$V_{AVDD\_RIPPLE} = V_{AVDD\_RIPPLE(C)} + V_{AVDD\_RIPPLE(ESR)}$$

$$V_{AVDD\_RIPPLE(C)} \approx \frac{I_{AVDD}}{C_{AVDD}} \left( \frac{V_{AVDD} - V_{VIN}}{V_{AVDD} f_{SW}} \right)$$

and:

$$V_{AVDD\_RIPPLE(ESR)} \approx I_{AVDD\_PEAK} R_{ESR\_AVDD}$$

where  $I_{AVDD\_PEAK}$  is the peak inductor current (see the *Inductor Selection* section). For ceramic capacitors, the output-voltage ripple is typically dominated by  $V_{AVDD\_RIPPLE(C)}$ . The voltage rating and temperature characteristics of the output capacitor must also be considered. Note that all ceramic capacitors typically have large temperature coefficient and bias voltage coefficients. The actual capacitor value in circuit is typically significantly less than the stated value.

### Input Capacitor Selection

The input capacitor reduces the current peaks drawn from the input supply and reduces noise injection into the IC. Two  $10\mu F$  ceramic capacitors are used in the typical operating circuit (Figure 1) because of the high source impedance seen in typical lab setups. Actual applications usually have much lower source impedance

# Low-Cost, Multiple-Output Power Supply for LCD TVs

since the step-up regulator often runs directly from the output of another regulated supply. Typically, the input capacitance can be reduced below the values used in the typical operating circuit.

## Rectifier Diode

The MAX17113's high switching frequency demands a high-speed rectifier. Schottky diodes are recommended for most applications because of their fast recovery time and low forward voltage. In general, a 2A Schottky diode complements the internal MOSFET well.

## Output-Voltage Selection

The output voltage of the step-up regulator can be adjusted by connecting a resistive voltage-divider from the output ( $V_{AVDD}$ ) to AGND with the center tap connected to FB1 (see Figure 1). Select R4 in the 10k $\Omega$  to 50k $\Omega$  range. Calculate R3 with the following equation:

$$R3 = R4 \times \left( \frac{V_{AVDD}}{V_{FB1}} - 1 \right)$$

where  $V_{FB1}$ , the step-up regulator's feedback set point, is 1.25V. Place R4 and R3 close to the IC.

## Loop Compensation

Choose  $R_{COMP}$  (R5 in Figure 1) to set the high-frequency integrator gain for fast transient response. Choose  $C_{COMP}$  (C17 in Figure 1) to set the integrator zero to maintain loop stability.

For low-ESR output capacitors, use the following equations to obtain stable performance and good transient response:

$$R_{COMP} \approx \frac{125 \times V_{VIN} \times V_{AVDD} \times C_{AVDD}}{L_{AVDD} \times I_{AVDD(MAX)}}$$

$$C_{COMP} \approx \frac{V_{AVDD} \times C_{AVDD}}{1250 \times I_{AVDD(MAX)} \times R_{COMP}}$$

To further optimize transient response, vary  $R_{COMP}$  in 20% steps and  $C_{COMP}$  in 50% steps while observing transient response waveforms.

## Charge-Pump Regulators

### Selecting the Number of Charge-Pump Stages

For highest efficiency, always choose the lowest number of charge-pump stages that meet the output requirement.

The number of positive charge-pump stages is given by:

$$n_{POS} = \frac{V_{GON} + V_{DROPOUT} - V_{AVDD}}{V_{SWO} - 2 \times V_D}$$

where  $n_{POS}$  is the number of positive charge-pump stages,  $V_{GON}$  is the output of the positive charge-pump

regulator,  $V_{SWO}$  is the supply voltage of the positive charge-pump regulators,  $V_D$  is the forward voltage drop of the charge-pump diode, and  $V_{DROPOUT}$  is the dropout margin for the regulator. Use  $V_{DROPOUT} = 300\text{mV}$ .

The number of negative charge-pump stages is given by:

$$n_{NEG} = \frac{-V_{GOFF} + V_{DROPOUT}}{V_{VIN} - 2 \times V_D}$$

where  $n_{NEG}$  is the number of negative charge-pump stages and  $V_{GOFF}$  is the output of the negative charge-pump regulator.

The above equations are derived based on the assumption that the first stage of the positive charge pump is connected to  $V_{AVDD}$  and the first stage of the negative charge pump is connected to ground. Sometimes fractional stages are more desirable for better efficiency. This can be done by connecting the first stage to  $V_{OUT}$  or another available supply. If the first charge-pump stage is powered from  $V_{OUT}$ , then the above equations become:

$$n_{POS} = \frac{V_{GON} + V_{DROPOUT} - V_{OUT}}{V_{SWO} - 2 \times V_D}$$

$$n_{NEG} = \frac{-V_{GOFF} + V_{DROPOUT} + V_{OUT}}{V_{VIN} - 2 \times V_D}$$

## Flying Capacitors

Increasing the capacitance of the flying capacitors (connected to DRVN and DRVP) value lowers the effective source impedance and increases the output-current capability. Increasing the capacitance indefinitely has a negligible effect on output-current capability because the internal switch resistance and the diode impedance place a lower limit on the source impedance. A 0.1 $\mu\text{F}$  ceramic capacitor works well in most low-current applications. The flying capacitor's voltage rating must exceed the following:

$$V_{CX} > n \times V_{SWO}$$

where  $n$  is the stage number in which the flying capacitor appears.

## Charge-Pump Output Capacitor

Increasing the output capacitance or decreasing the ESR reduces the output ripple voltage and the peak-to-peak transient voltage. With ceramic capacitors, the output-voltage ripple is dominated by the capacitance value. Use the following equation to approximate the required capacitor value:

$$C_{OUT\_CP} \geq \frac{I_{LOAD\_CP}}{2f_{OSC} V_{RIPPLE\_CP}}$$

# Low-Cost, Multiple-Output Power Supply for LCD TVs

where  $C_{OUT\_CP}$  is the output capacitor of the charge pump,  $I_{LOAD\_CP}$  is the load current of the charge pump, and  $V_{RIPPLE\_CP}$  is the peak-to-peak value of the output ripple.

## Output-Voltage Selection

Adjust the positive charge-pump regulator's output voltage by connecting a resistive voltage-divider from the SRC output to AGND with the center tap connected to FBP (Figure 1). Select the lower resistor of divider R17 in the 10k $\Omega$  to 30k $\Omega$  range. Calculate the upper resistor, R16, with the following equation:

$$R17 = R16 \times \left( \frac{V_{GON}}{V_{FBP}} - 1 \right)$$

where  $V_{FBP} = 1.25V$  (typ).

Adjust the negative charge-pump regulator's output voltage by connecting a resistive voltage-divider from  $V_{GOFF}$  to REF with the center tap connected to FBN (Figure 1). Select R2 in the 20k $\Omega$  to 50k $\Omega$  range. Calculate R1 with the following equation:

$$R1 = R2 \times \frac{V_{FBN} - V_{GOFF}}{V_{REF} - V_{FBN}}$$

where  $V_{FBN} = 250mV$ ,  $V_{REF} = 1.25V$ . Note that REF can only source up to 50 $\mu A$ , using a resistor less than 20k $\Omega$  for R1 results in higher bias current than REF can supply.

## PCB Layout and Grounding

Careful PCB layout is important for proper operation. Use the following guidelines for good PCB layout:

- Minimize the area of respective high-current loops by placing each DC-DC converter's inductor, diode, and output capacitors near its input capacitors and its LX\_ and GND\_ pins. For the step-down regulator, the high-current input loop goes from the positive terminal of the input capacitor to the IC's IN pin, out of LX2, to the inductor, to the positive terminals of the output capacitors, reconnecting the output capacitor and input capacitor ground terminals. The high-current output loop is from the inductor to the positive terminals of the output capacitors, to the negative terminals of the output capacitors, and to the Schottky diode (D2). For the step-up regulator, the high-current input loop goes from the positive terminal of the input capacitor to the inductor, to the IC's LX1 pin, out of PGND, and to the input capacitor's negative terminal. The high-current output loop is from the positive terminal of the input capacitor to the inductor, to the output diode (D1), to the positive terminal of the output capacitors, reconnecting between the output capacitor and

input capacitor ground terminals. Connect these loop components with short, wide connections. Avoid using vias in the high-current paths. If vias are unavoidable, use many vias in parallel to reduce resistance and inductance.

Create a power ground island for the step-down regulator, consisting of the input and output capacitor grounds and the diode ground. Connect all these together with short, wide traces or a small ground plane. Similarly, create a power ground island (PGND) for the step-up regulator, consisting of the input and output capacitor grounds and the PGND pin. Create a power ground island (CPGND) for the positive and negative charge pumps, consisting of the output (SRC,  $V_{GOFF}$ ) capacitor grounds, and negative charge-pump diode ground. Connect CPGND ground plane to PGND together with wide traces. Maximizing the width of the power ground traces improves efficiency and reduces output-voltage ripple and noise spikes.

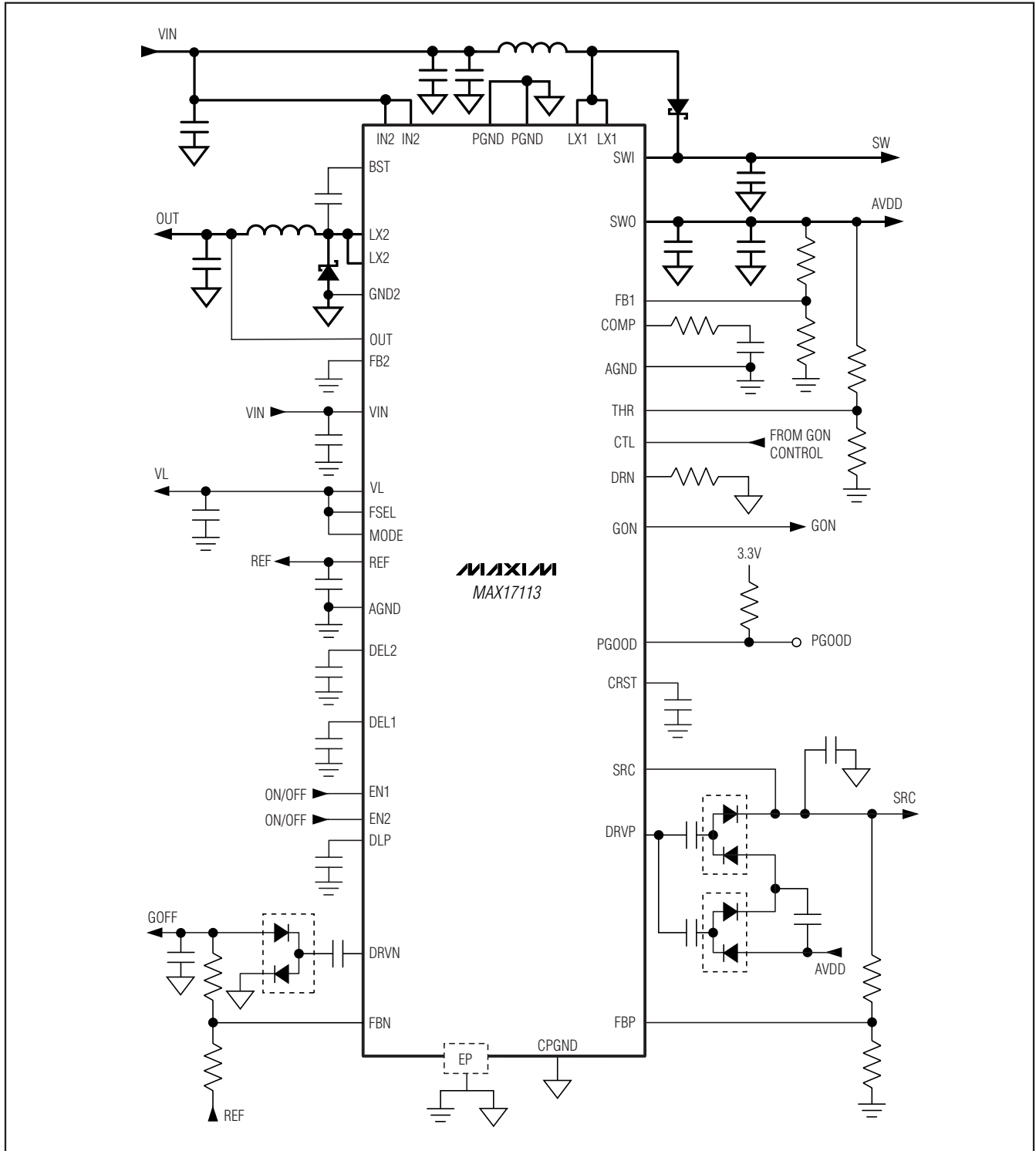
- Create an analog ground plane (AGND) consisting of the AGND pin, all the feedback divider ground connections, the COMP and DEL capacitor ground connections, and the device's exposed backside pad. Connect PGND and AGND islands by connecting the two ground pins directly to the exposed backside pad. Make no other connections between the PGND and AGND ground planes.
- Place all feedback voltage-divider resistors as close as possible to their respective feedback pins. The divider's center trace should be kept short. Placing the resistors far away causes their FB traces to become antennas that can pick up switching noise. Care should be taken to avoid running any feedback trace near LX1, LX2, DRVP, or DRVN.
- Place VIN pin, VL pin, and REF pin bypass capacitors as close as possible to the device. The ground connection of the VL bypass capacitor should be connected directly to the AGND pin with a wide trace.
- Minimize the length and maximize the width of the traces between the output capacitors and the load for best transient responses.
- Minimize the size of the LX1 and LX2 nodes while keeping them wide and short. Keep the LX1 and LX2 nodes away from feedback nodes (FB1, FB2, FBP, and FBN) and analog ground. Use DC traces as a shield, if necessary.

Refer to the MAX17113 evaluation kit for an example of proper board layout.

# Low-Cost, Multiple-Output Power Supply for LCD TVs

## Simplified Operating Circuit

MAX17113



# Low-Cost, Multiple-Output Power Supply for LCD TVs

## Chip Information

PROCESS: BiCMOS

## Package Information

For the latest package outline information and land patterns, go to [www.maxim-ic.com/packages](http://www.maxim-ic.com/packages).

| PACKAGE TYPE | PACKAGE CODE | DOCUMENT NO.            |
|--------------|--------------|-------------------------|
| 40 TQFN-EP   | T4055+1      | <a href="#">21-0140</a> |

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

30 **Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600**

## Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

 [View MAX17113ETL+ on WIN SOURCE](#)

 [Maxim Integrated Information](#)

## Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management